

System-Side Impedance Track™ Fuel Gauge With Direct Battery Connection

FEATURES

- Battery Fuel Gauge for 1-Series Li-Ion Applications
- Resides on System Main Board
- Works with Embedded or Removable Battery Packs
- Uses PACK+, PACK- and T Battery Terminals
- Can be Powered Directly From Battery Pack (no LDO required)
- Microcontroller Peripheral Provides:
 - **Battery Low** Interrupt Warning
 - **Battery Insertion** Indicator
- 96 Bytes of Non-Volatile Scratch Pad FLASH
- Battery Fuel Gauging Based on Patented Impedance Track™ Technology
- Models Battery Discharge Curve for Accurate Time-To-Empty Predictions
- Automatically Adjusts for Battery Aging, Battery Self-Discharge and Temperature/Rate Inefficiencies
- Low-Value Sense Resistor (10mΩ or less)
- I²C™ for Connection to System Microcontroller Port
- Small 2-pin 2,5mm⁴mm SON Package

APPLICATIONS

- Smartphones
- PDAs
- Digital Still and Video Cameras
- Handheld Terminals
- MP3 Multimedia Players

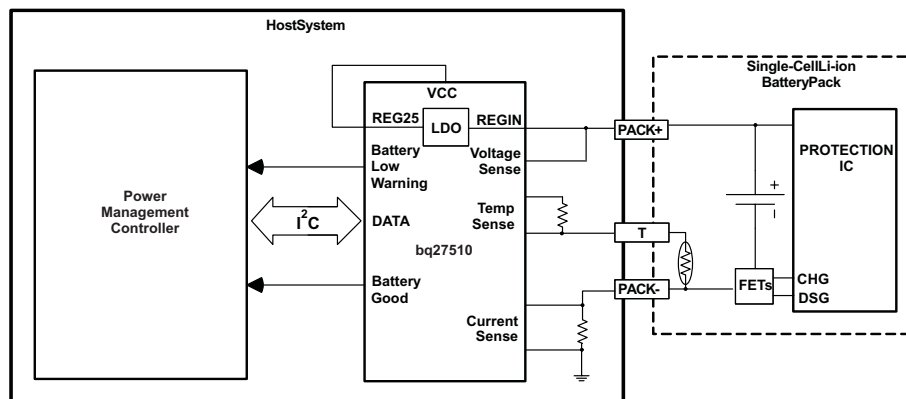
DESCRIPTION

The Texas Instruments bq27510 system-side Li-Ion battery fuel gauge is a microcontroller peripheral that provides fuel gauging for single-cell Li-Ion battery packs. It requires no system microcontroller firmware development. The bq27510 resides on the system's main board and manages an embedded battery (non-removable) or a removable battery pack.

The bq27510 uses the patented Impedance Track™ algorithm for fuel gauging and provides information such as remaining capacity (Ah), state-of-charge (%), run-time to empty (min.), battery voltage (mV) and temperature (°C).

Battery fuel gauging with the bq27510 requires only PACK+, PACK-, and T (thermistor) connections to a battery pack or embedded battery.

TYPICAL APPLICATION



Please be aware that an important notice concerning availability, standard warranty and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

Impedance Track is a trademark of Texas Instruments.
I²C is a trademark of Phillips Corporation.

PRODUCTION INFORMATION: This document is current as of the date of publication. It is subject to change without notice. The information in this document is provided for information only. It is not intended to be used for any other purpose. The information in this document is provided for information only. It is not intended to be used for any other purpose. The information in this document is provided for information only. It is not intended to be used for any other purpose.

Copyright © 2009 Texas Instruments Incorporated



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

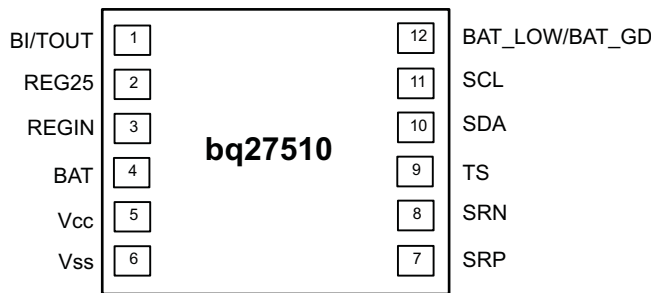
DEVICE INFORMATION

AVAILABLE OPTIONS

PART NUMBER	PACKAGE ⁽¹⁾	TA	COMMUNICATION REEL FORMAT	QUANTITY
bq27510DRZR-G1	12-pin 2,5-mm x 4-mm QFN	-40 to 85°C	I ² C	3000
bq27510DRZT-G1				250

(1) For the most current package and ordering information see the Package Option Addendum at the end of this document or see the TI website at www.ti.com.

PIN DIAGRAM



TERMINAL FUNCTIONS

TERMINAL NAME	(1)	DESCRIPTION
Battery-instruction input		Power input for the microcontroller network. Thermistor-multiplexed control pin. Push-pull I/O with pull-up resistor >1M Ω (1.8M Ω typical).
2.5V output voltage of REG25	0.47	μF ceramic capacitor.
1.5V output voltage of REGIN	0.1	μF ceramic capacitor.
BAT		Cell voltage measurement input (ADC input).
Vcc	0.47	μF ceramic capacitor connected to REG25 should be closed to cc.
Vss	6	Device ground.
SRP		Analogue pin connected to the external coulomb counter where SRP is nearest the system PACK-connection. Connect 5-m Ω to 20-m Ω sense resistor.
SRN		Analogue pin connected to the external coulomb counter where SRN is nearest the /ss connection. Connect 5-m Ω to 20-m Ω sense resistor.
TS		Package thermistor voltage sense (used 03AT-type thermistor) ADC input.
SDA	10	² Serial communications data line for communication with system (Master) Open-drain I/O. Use with 10-k Ω pull-up resistor (typical).
SCISlave I	11	² Serial communications clock input for communication with system (Master) Open-drain I/O. Use with 10-k Ω pull-up resistor (typical).
Battery-low output indicator		Desired function polarity selected through the Operation Configuration register. Open-drain output.

(1) Digital input/output, Analog input, Power connection.

ELECTRICAL SPECIFICATIONS

ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range (unless otherwise noted) ⁽¹⁾

		VALUE	UNIT
V _{REGIN}	Regulator input voltage	-0.3 to 2.4	V
V _{CC}	Supply voltage range	-0.3 to 2.75	V
V _{IOD}	Open-drain/Quin (SDASCLBAT_LOW/BAT_GD)	-0.3 to 6	V
V _{BAT}	BAT pin input	-0.3 to 6	V
V _I	Input voltage range at the pins (TSSRPSRNBI/TOUT)	-0.3 to V _{CC} + 0.3	
T _F	Functional temperature range	-40 to 100	°C
T _{STG}	Storage temperature range	-65 to 150	°C
ESD	Human Body Mode (HBM) BAT pin	1.5	KV
	Human Body Mode (HBM) all the pins	2	

Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

DISSIPATION RATINGS

PACKAGE	T _A ≤ 40°C POWER RATING	DERATING FACTOR T _A ≤ 40°C	R _{θJA}
12-pin DRZ ⁽¹⁾	482 mW	5.67 mW/°C	176°C/W

This data is based on using a 4-layer EDE high-board with the exposed die pad connected to a copper pad on the board. The board pads are connected to the ground plane by 2-via matrix.

RECOMMENDED OPERATING CONDITIONS

T_A = 25°C and / REGIN = ±V BAT = 3.6 (unless otherwise noted)

PARAMETER	TEST CONDITION	MIN	MAX	
V _{REGIN}	Supply voltage	No operating restrictions		V
		2.45	5.5	
I _{CC}	Normal operating mode current Fue (auger) NORMAL mode, I _{LOAD} > <i>Sleep Current</i>	103		μA
I _{SLEP}	Low-power operating mode current Fue (auger) SLEEP mode, I _{LOAD} < <i>Sleep Current</i>	18		μA
I _{HIB}	Hibernate operating mode current Fue (auger) HIBERNATE mode, I _{LOAD} < <i>Hibernate Current</i>	4		μA
V _{OL}	Output voltage low (Pins 1, 0, 1, 1, 2) I _{OL} = 3 mA	V - 0.4		
V _{OH(PP)}	Output high voltage (Pin 1) I _{OH} = -1 mA	V _{CC} - 0.5		V
V _{OH(OD)}	Output high voltage (Pins 0, 1, 1, 2) External pull-up resistor connected to V _{CC}	V _{CC} - 0.5		V
V _{IL}	Input voltage low (Pins 1, 0, 1, 1, 2)	-0.3	0.6	V
V _{IH(OD)}	Input voltage high (Pins 1, 0, 1, 1, 2)	1.2	6	V
V _{A1}	Input voltage range (TS)	V _{SS} - 0.125		V
V _{A2}	Input voltage range (BAT)	V _{SS} - 0.125		V
V _{A3}	Input voltage range (SRPSRN)	V _{SS} - 0.125		0.125
t _{PUCD}	Power-up communication delay	250		ms

POWER-ON RESET

T_A = 40°C to 85°C, C_{REG} = 0.47 μF, 2.45 A / REGIN = ±V BAT = 5.5 / typical values at T_A = 25°C and / REGIN = ±V BAT = 3.6 / (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	MAX
V _{IT+}	Positive-going battery voltage input / V _{CC}	2.0	
V _{HYS}	Power-on reset hysteresis	100	55

2.5 LDO REGULATOR (1)

$T_A = -40^{\circ}\text{C}$ to 85°C , $C_{REG} = 0.47 \mu\text{F}$, 2.45V $V_{REGIN} \approx V_{BAT} - 0.5\text{V}$ (typical values at $T_A = 25^{\circ}\text{C}$ and $V_{REGIN} \approx V_{BAT} - 0.6\text{V}$ (unless otherwise noted)

PARAMETER		TEST CONDITION		MIN/MAX	
V_{REG25}	Regulator output voltage	$2.7\text{V} \leq V_{REGIN} \leq 5.5\text{V}$, $I_{OUT} \leq 16\text{mA}$	$T_A = -40^{\circ}\text{C}$ to 85°C		
		$2.45\text{V} \leq V_{REGIN} \leq 2.7\text{V}$ (low battery) $I_{OUT} \leq 3\text{mA}$	$T_A = -40^{\circ}\text{C}$ to 85°C		V
V_{DO}	Regulator dropout voltage	2.7V $I_{OUT} \leq 10\text{mA}$	$T_A = -40^{\circ}\text{C}$ to 85°C		280
		2.45V $I_{OUT} \leq 3\text{mA}$			50
$\Delta V_{REGTEMP}$	Regulator output change with temperature	$V_{REGIN} = 3.6\text{V}$ $I_{OUT} = 10\text{mA}$	$T_A = -40^{\circ}\text{C}$ to 85°C		0.3%
$\Delta V_{REGLINE}$	Line regulation	$2.7\text{V} \leq V_{REGIN} \leq 5.5\text{V}$ $I_{OUT} = 10\text{mA}$			mV 11
$\Delta V_{REGLOAD}$	Load regulation	$0.2\text{mA} \leq I_{OUT} \leq 3\text{mA}$ $V_{REGIN} = 2.45\text{V}$			mV 34
		$3\text{mA} \leq I_{OUT} \leq 10\text{mA}$ $V_{REGIN} = 2.7\text{V}$			31
$I_{SHORT}^{(2)}$	Short-circuit current limit	$V_{REG25} = 0\text{V}$	$T_A = -40^{\circ}\text{C}$ to 85°C		mA 50

(1) Output current (I_{OUT}) is the sum of internal and external load currents.
 (2) Assured by design. No production tested.

INTERNAL TEMPERATURE SENSOR CHARACTERISTICS

$T_A = -40^{\circ}\text{C}$ to 85°C , $C_{REG} = 0.47 \mu\text{F}$, 2.45V $V_{REGIN} \approx V_{BAT} - 0.5\text{V}$ (typical values at $T_A = 25^{\circ}\text{C}$ and $V_{REGIN} \approx V_{BAT} - 0.6\text{V}$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN/MAX	
G_{TEMP}	Temperature sensor voltage gain			-2	mV/°C

HIGH FREQUENCY OSCILLATOR

$T_A = -40^{\circ}\text{C}$ to 85°C , $C_{REG} = 0.47 \mu\text{F}$, 2.45V $V_{REGIN} \approx V_{BAT} - 0.5\text{V}$ (typical values at $T_A = 25^{\circ}\text{C}$ and $V_{REGIN} \approx V_{BAT} - 0.6\text{V}$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN/MAX	
f_{OSC}	Operating frequency			2.097	MHz
f_{EIO}	Frequency error (1)(2)	$T_A = 0^{\circ}\text{C}$ to 60°C		-0.33%	
		$T_A = -20^{\circ}\text{C}$ to 70°C		-0.33%	
		$T_A = -40^{\circ}\text{C}$ to 85°C		-0.33%	
t_{SXO}	Start-up time (3)			ms 5 2.5	

(1) The frequency error is measured from 2.097 MHz.
 (2) The frequency drifts included and measured from the trimmed frequency.
 (3) The start-up time is defined as the time it takes for the oscillator output frequency to be 3% of typical oscillator frequency.
 $C_C = 2.5\mu\text{F}$ $T_A = 25^{\circ}\text{C}$.

LOW FREQUENCY OSCILLATOR

$T_A = -40^{\circ}\text{C}$ to 85°C , $C_{REG} = 0.47 \mu\text{F}$, $I_{F2.45A}$, $V_{REGIN} = V$, $V_{BAT} = 5.5$ (typical values at $T_A = 25^{\circ}\text{C}$ and $V_{REGIN} = V$, $V_{BAT} = 3.6$)
 (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	MAX
f_{OSC} Operating frequency		32.768	KHz
f_{EIO} Frequency error ⁽¹⁾⁽²⁾	$T_A = 0^{\circ}\text{C}$ to 60°C	-1.5	1.5%
	$T_A = -20^{\circ}\text{C}$ to 70°C	-2.5	2.5%
	$T_A = 40^{\circ}\text{C}$ to 85°C	-4.0	4.0%
t_{SXO} Start-up time ⁽³⁾		500	μs

⁽¹⁾The frequency drifts included and measured from the trimmed frequency at $V_{CC} = 2.5\text{V}$, $T_A = 25^{\circ}\text{C}$.

⁽²⁾The frequency error is measured from 32.768 KHz.

⁽³⁾The start-up time is defined as the time it takes for the oscillator output frequency to be 3% of typical oscillator frequency.

INTEGRATING ADC (COULOMB COUNTER) CHARACTERISTICS

$T_A = -40^{\circ}\text{C}$ to 85°C , $C_{REG} = 0.47 \mu\text{F}$, $I_{F2.45A}$, $V_{REGIN} = V$, $V_{BAT} = 5.5$ (typical values at $T_A = 25^{\circ}\text{C}$ and $V_{REGIN} = V$, $V_{BAT} = 3.6$)
 (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	MAX
V_{SR_IN} Input voltage range $V_{(SRN)}$ and $V_{(SRP)}$	$V_{SR} = V_{(SRN)}$ to $V_{(SRP)}$	-0.125	0.125
t_{SR_CONV} Conversion time	Single conversion	1	s
Resolution		14	bit\$5
V_{SR_OS} Input offset		140	μV
I_{NL} Integrator nonlinearity error		± 0.007	FSR
Z_{SR_IN} Effective input resistance ⁽¹⁾		2.5	M Ω
I_{SR_LKG} Input leakage current ⁽¹⁾		0.3	μA

(Asured by design No production tested.)

ADC TEMPERATURE AND CELL MEASUREMENT CHARACTERISTICS

$T_A = -40^{\circ}\text{C}$ to 85°C , $C_{REG} = 0.47 \mu\text{F}$, $I_{F2.45A}$, $V_{REGIN} = V$, $V_{BAT} = 5.5$ (typical values at $T_A = 25^{\circ}\text{C}$ and $V_{REGIN} = V$, $V_{BAT} = 3.6$)
 (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	MAX
V_{ADC_IN} Input voltage range		-0.2	V 1
t_{ADC_CONV} Conversion time		16	ms\$25
Resolution		14	bit\$5
V_{ADC_OS} Input offset		1	mV
Z_{ADC1} Effective input resistance (TS) ⁽¹⁾		8	M Ω
Z_{ADC2} Effective input resistance (BAT) ⁽¹⁾	bq27510 measuring cell voltage	8	M Ω
	bq27510 measuring cell voltage	100	k Ω
I_{ADC_LKG} Input leakage current ⁽¹⁾		0.3	μA

(Asured by design No production tested.)

DATA FLASH MEMORY CHARACTERISTICS

$T_A = -40^{\circ}\text{C}$ to 85°C , $C_{REG} = 0.47 \mu\text{F}$, $I_{F2.45A}$, $V_{REGIN} = V$, $V_{BAT} = 5.5$ (typical values at $T_A = 25^{\circ}\text{C}$ and $V_{REGIN} = V$, $V_{BAT} = 3.6$)
 (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	MAX
t_{DR} Data retention ⁽¹⁾		10	Years
Flash programming write-cycles ⁽¹⁾		20,000	Cycles
$t_{WORDPROG}$ Word programming time ⁽¹⁾		2	ms
I_{CCPROG} Flash-write supply current ⁽¹⁾		5	mA

(Asured by design No production tested.)

I²C-COMPATIBLE INTERFACE COMMUNICATION TIMING CHARACTERISTICS

T_A = -40°C to 85°C, 2.4V/CC = 2.6 (typical values at T_A = 25°C and V_{CC} = 2.5 (unless otherwise noted))

PARAMETER		TEST CONDITIONS		
t _r	SCL/SDA rise time		nS	00
t _f	SCL/SDA fall time		nS	00
t _{w(H)}	SCL pulse width (high)		600	ns
t _{w(L)}	SCL pulse width (low)		1.3	µs
t _{su(STA)}	Setup time for repeated start		600	ns
t _{d(STA)}	Start first falling edge of SCL		600	ns
t _{su(DAT)}	Data setup time		100	ns
t _{h(DAT)}	Data hold time		0	ns
t _{su(STOP)}	Setup time for stop		600	ns
t _{BUF}	Bus free time between stop and start		66	µs
f _{SCL}	Clock frequency		k	00

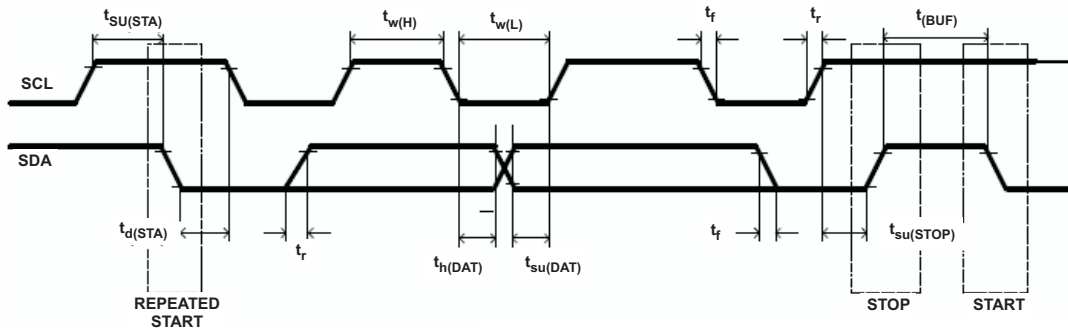


Figure 1 I²C-Compatible Interface Timing Diagrams

GENERAL DESCRIPTION

The bq27510 accurately predicts the battery capacity and the operational characteristics of a single Li-based rechargeable cell interrogated by system processor. It provides information such as state-of-charge (SOC), time-to-empty (TTE), and time-to-full (TTF).

Information is accessed through a series of commands called *Standard Commands*. Further capabilities are provided by the additional *Extended Commands*. See both sets of commands indicated by the general format *Command* are used to read and write information contained within the bq27510 control and status registers, as well as data flash locations. Commands are sent from system gauges using the bq27510's communication engine, or are executed during application development on a manufacturer end-equipment operation.

Cell information is stored in the bq27510 non-volatile flash memory. Many of these data flash locations are accessible during application development. They cannot generally be accessed directly during end-equipment operation. Access to these locations is achieved by either use of the bq27510's companion evaluation software, through individual commands or through a sequence of data-flash-access commands. To access desired data flash location, the correct data flash subclass and offset must be known.

The bq27510 provides 96 bytes of user-programmable data flash memory, partitioned into 32-byte blocks: **Manufacturer Info Block A**, **Manufacturer Info Block B**, and **Manufacturer Info Block C**. This data space is accessed through a data flash interface. For specific information on accessing the data flash section, see *Manufacturer Information Blocks*.

The bq27510's high-accuracy gauging prediction is Texas Instruments' proprietary Impedance Track Algorithm. This algorithm uses cell measurements, characteristics, and properties to create state-of-charge predictions that can achieve less than 1% error across a wide variety of operating conditions and over the lifetime of the battery.

The bq27510 measures charge/discharge activity by monitoring the voltage across a small-value series sense resistor (5mΩ to 20mΩ typ.) located between the system's S and the battery's PACK terminal. When the cell is attached to the bq27510, cell impedances are computed based on cell current, cell open-circuit voltage (OCV), and cell voltage under loading conditions.

The bq27510 external temperature sensing is optimized with the use of a high-accuracy negative temperature coefficient (NTC) thermistor with $R_{25} = 10.0k\Omega \pm 1\%$ (B25/853435K1% such as Semitec NTC103AT). The bq27510 can also be configured to use an internal temperature sensor. When an external thermistor is used, a 18.2k pull-up resistor between BT/TOU and S pins is also required. The bq27510 uses temperature to monitor the battery-pack environment which is used for fuel gauging and cell protection functionality.

To minimize power consumption, the bq27510 has several power modes: NORMAL, SLEEP, HIBERNATE, and BATTERY CHECK. The bq27510 passes automatically between these modes depending on the occurrence of specific events, though the system processor can initiate some of these modes directly. More details can be found in Section *Power Modes*.

NOTE:

FORMATTING CONVENTIONS IN THIS DOCUMENT:

Commands: *italics* with *parentheses* and *breaking spaces*, e.g. *RemainingCapacity()*.

Data Flash: *italics*, **bold** and *breaking spaces*, e.g. **DesignCapacity**.

Register bits and flags: brackets and *italics*, e.g. [TDA]

Data flash bits: brackets, *italics* and **bold**, e.g. [LED1]

Modes and states: ALL CAPITALS, e.g. UNSEALED mode.

DATA COMMANDS

Standard Data Commands

The bq27510 series of 1-byte standard commands enable system reading and writing of battery information. Each standard command has an associated command-code pair as indicated in [Table 1](#). Because each command consists of two consecutive 2-byte transmissions, the execution of the command function and the corresponding two bytes of data. Additional options for transferring data, such as pooling, are described in Section 12 (INTERFACE Standard Commands are accessible in NORMAL operation. Read/Write permission depends on the active access mode (SEALED or UNSEALED). For details on the SEALED and UNSEALED states, refer to Section 4 (Access Modes.)

Table 1. Standard Commands

NAME	COMMAND	UNSEALED	SEALED	ACCESS	
Control()	CNTL	0x00	0x01	N/A	R/W
AtRate()	AR	0x02	0x03	mA	R/W
AtRateTimeToEmpty()	Mix 0x04	0x05			R
Temperature()	TEMP	0x06	0x07	0.1K	R
Voltage()	VOLT	0x08	0x09	mV	R
Flags()	0x0A	0x0B			R
Nominal Available Capacity()	NAC	0x0C	0x0D	mAh	R
Full Available Capacity()	FAC	0x0E	0x0F	mAh	R
Remaining Capacity()	RM	0x10	0x11	mAh	R
Full Charge Capacity()	FCC	0x12	0x13	mAh	R
Average Current()	AI	0x14	0x15	mA	R
Time To Empty()	TTE	Mix 0x16			R
Time To Full()	TTF	Mix 0x18			R
Standby Current()	SI	0x1A	0x1B	mA	R
Standby Time To Empty()	STTE	Mix 0x1C			R
Max Load Current()	MLI	0x1E	0x1F	mA	R
Max Load Time To Empty()	Mix 0x20	0x21			R
Available Energy()	AE	Mix 0x22	0x23		R
Average Power()	AP	0x24	0x25	mW	R
TTE at Constant Power()	Mix 0x26	0x27			R
Reserved	RSVD	0x28	0x29	N/A	R
Cycle Count()	CC	0x2A	0x2B		R
State Of Charge()	SOC	0x2C	0x2D	%	R

Control() 0x00/0x01

Issuing Control() command requires subsequent 2-byte subcommand. These additional bytes specify the particular control function desired. The Control() command allows the system to control specific features of the bq27510 during normal operation and additional features when the bq27510 is in a different access mode as described in [Table 2](#).

Table 2. Control() Subcommands

CNTL	UNSEALED	SEALED	DESCRIPTION	ACCESS
CONTROL_STATUS	0x00	0x01	Checksum, Hibernate, etc.	
DEVICE_TYPE	0x02	0x03	Report device type (bq27510)	
FW_VERSION	0x04	0x05	Report firmware version on the device type	
HW_VERSION	0x06	0x07	Report hardware version on the device type	
DF_CHECKSUM	0x08	0x09	Enable/disable checksum to be generated and reported on read	
RESET_DATA	0x0A	0x0B	Return to 0x0000	

Table 2. Control Subcommands (continued)

CONTROL SUBCOMMAND	DESCRIPTION	ACCESS
Reserved	Not used	
PREV_MACWRITE	Return previous MAC command code	
CHEM_ID	Report chemical identification of the impedance Track™ configuration	
BOARD_OFFSET	Force the bq27510 to measure and store the board offset	
CC_INT_OFFSET	Force the bq27510 to measure the internal CC offset	
WRITE_CC_INT_OFFSET	Force the bq27510 to store the internal CC offset	
SET_HIBERNATE	Force CONTROL_STATUS register bit HIBERNATE to 1	
CLEAR_HIBERNATE	Force CONTROL_STATUS register bit HIBERNATE to 0	
SEALED	Place the bq27510 in SEALED access mode	
IT_ENABLE	Enable impedance Track™ algorithm	
IF_CHECKSUM	Report the next action flash checksum	
CAL_MODE	Place the bq27510 in calibration mode	
RESET	Force the bq27510 to reset	

CONTROL_STATUS0x0000

Instruct the fuel gauge to return status information to control addresses 0x00/0x01. The status word includes the following information.

Table 3. CONTROL_STATUS Bit Definitions

	bit7	bit6	bit5	bit4	bit3	bit2	bit1	bit0
– High Byte		FAS	SS	CCA	CSV		–	–
HIBERNATE Low Byte			BC	QEN	RUP	LD		

- FAS Status bit indicating the bq27510 is in FULL ACCESS SEALED state. Active when set.
- SS Status bit indicating the bq27510 is in SEALED state. Active when set.
- CSV Status bit indicating valid data flash checksum has been generated. Active when set.
- CCA Status bit indicating the bq27510 coulomb count calibration routine is active. Active when set.
- BC Status bit indicating the bq27510 board calibration routine is active. Active when set.
- HIBERNATE Status bit indicating request to enter into HIBERNATE from SLEEP mode. True when set. Default is 0.
- SLEEP Status bit indicating the bq27510 is in SLEEP mode. True when set.
- LD Status bit indicating the bq27510 impedance Track™ algorithm using constant-power mode. True when set. Default is 0.
- RUP_DIS Status bit indicating the bq27510 Rable updates disabled. True when set.
- VOIS Status bit indicating the voltage source OK. Qmax updates. True when set.
- QEN Status bit indicating the bq27510 Qmax updates enabled. True when set.

DEVICE_TYPE0x0001

Instruct the fuel gauge to return the device type to addresses 0x00/0x01.

FW_VERSION0x0002

Instruct the fuel gauge to return the firmware version to addresses 0x00/0x01.

HW_VERSION0x0003

Instruct the fuel gauge to return the hardware version to addresses 0x00/0x01.

DF_CHECKSUM0x0004

Instruct the fuel gauge to compute the checksum of the data flash memory. The checksum values are written and returned to addresses 0x00/0x01 (UNSEALED mode only). The checksum will be calculated in SEALED mode however the checksum value can still be read.

RESET_DATA0x0005

Instructs the gauge to return the reset data addresses 0x00/0x01 with the low byte (0x00) being the number of full resets and the high byte (0x01) the number of partial resets.

PREV_MACWRITE0x0007

Instructs the gauge to return the previous command written to addresses 0x00/0x01.

CHEM_ID0x0008

Instructs the gauge to return the chemical identifier for the Impedance Track™ configuration to addresses 0x00/0x01.

BOARD_OFFSET0x0009

Instructs the gauge to compute the coulomb counted offset with internal short and then without internal short applied across the SR inputs. The difference between the two measurements is the board offset. After a delay of approximately 32 seconds, this offset value is returned to addresses 0x00/0x01 and written to data flash. The CONTROL_STATUS\$BCA also sets the sense to prevent any charge/discharge current from flowing during the process. This function is only available when the gauge is UNSEALED. When SEALED, this command only reads back the board offset value stored in data flash.

CC_INT_OFFSET0x000A

Control data 0x000A instructs the gauge to compute the coulomb counted offset with internal short applied across the SR inputs. The offset value is returned to addresses 0x00/0x01 after a delay of approximately 16 seconds. This function is only available when the gauge is UNSEALED. When SEALED, this command only reads back the CC_INT_OFFSET value stored in data flash.

WRITE_OFFSET0x000B

Control data 0x000B causes the gauge to write the coulomb counted offset to data flash.

SET_HIBERNATE0x0011

Instructs the gauge to force the CONTROL_STATUS\$HIBERNATE bit. This allows the gauge to enter the HIBERNATE power mode after the transition to SLEEP power state is detected. The HIBERNATE bit is automatically cleared upon exiting from HIBERNATE mode.

CLEAR_HIBERNATE0x0012

Instructs the gauge to force the CONTROL_STATUS\$HIBERNATE bit. This prevents the gauge from entering the HIBERNATE power mode after the transition to SLEEP power state is detected. It can also be used to force the gauge out of HIBERNATE mode.

SEALED0x0020

Instructs the gauge to transition from UNSEALED state to SEALED state. The gauge should always be set to SEALED state for end equipment.

IT_ENABLE0x0021

This command forces the gauge to begin the Impedance Track™ algorithm, sets the active Update Status location to 0x0, and causes the VOK and QEN flags to set in the CONTROL_STATUS register. VOK is cleared if the voltage is not suitable for Qmax update. Once set, QEN cannot be cleared. This command is only available when the gauge is UNSEALED.

IF_CHECKSUM0x0022

This command instructs the gauge to compute the instruction flash checksum. When the checksum has been calculated and stored, the CONTROL_STATUS\$CVS is set. In UNSEALED mode, the checksum value is returned to addresses 0x00/0x01. The checksum will be calculated in SEALED mode, however, the checksum value can still be read.

CAL_MODE0x0040

This command instructs the fuel gauge to enter calibration mode. This command is only available when the fuel gauge is UNSEALED.

RESET0x0041

This command instructs the fuel gauge to perform a full reset. This command is only available when the fuel gauge is UNSEALED.

AtRate()0x02/0x03

The AtRate() read/write-word function in the first two-function commands sets the AtRate() value used in calculations made by the AtRateTimeToEmpty() function. The AtRate() units are mA.

The AtRate() value is signed integer with negative value interpreted as discharge current value. The AtRateTimeToEmpty() function returns the predicted operating time at the AtRate() value discharge. The default value for AtRate() is zero. Both the AtRate() and AtRateTimeToEmpty() commands should only be used in NORMAL mode.

AtRateTimeToEmpty()0x04/0x05

This read-word function returns an unsigned integer value of the predicted remaining operating time if the battery is discharged at the AtRate() value in minutes with a range of 0 to 65,534. A value of 65,535 indicates the fuel gauge updates AtRateTimeToEmpty() within a few seconds. The fuel gauge automatically updates AtRateTimeToEmpty() based on the AtRate() value every 1 second. Both the AtRate() and AtRateTimeToEmpty() commands should only be used in NORMAL mode.

Temperature()0x06/0x07

This read-word function returns an unsigned integer value of the battery temperature in units of 0.1 K measured by the fuel gauge.

Voltage()0x08/0x09

This read-word function returns an unsigned integer value of the measured cell-pack voltage in mV with a range of 0 to 6000 mV.

Flags()0x0a/0x0b

This read-word function returns the contents of the gas-gauge status register depicting the current operating status.

Table 4. Flags Bit Definitions

	bit7	bit6	bit5	bit4	bit3	bit2	bit1	bit0
OTD - High Byte			-	FCHG				CHG
- Low Byte		OCV_GOOD						

- OTD - Over-Temperature charge condition detected. True when set.
- OTD - Over-Temperature discharge condition detected. True when set.
- CHG_INH - Charge inhibit unable to begin charging temp outside range. **[ChargeInhibitTempLow, ChargeInhibitTempHigh]**. True when set.
- XCHG - Charge Suspend Alert (temp outside range). **[SuspendTempLow, SuspendTempHigh]**. True when set.
- FC - Full-charge condition reached. True when set.
- CHG - Fast charging allowed. True when set.
- OCV_GOOD - Good DCV measurement taken. True when set.
- WAIT_ID - Waiting to identify inserted battery. True when set.
- BAT_DET - Battery detected. True when set.
- SOC - State-of-Charge-Threshold **(SOCSet)** reached. True when set.
- SOC - State-of-Charge-Threshold Final **(SOCSet%)** reached. True when set.

DSDischargingDetectedTruevhwset.

NominalAvailableCapacity(0x0c/0x0d)

This read-only command pair returns the uncompensated (less than C/20 load) battery capacity remaining Units are mAh.

FullAvailableCapacity(0x0e/0x0f)

This read-only command pair returns the uncompensated (less than C/20 load) capacity of the battery when fully charged Units are mAh. *FullAvailableCapacity* is updated at regular intervals as specified by the Algorithm.

RemainingCapacity(0x10/0x11)

This read-only command pair returns the compensated battery capacity remaining Units are mAh.

FullChargeCapacity(0x12/0x13)

This read-only command pair returns the compensated capacity of the battery when fully charged Units are mAh. *FullChargeCapacity* is updated at regular intervals as specified by the Algorithm.

AverageCurrent(0x14/0x15)

This read-only command pair returns signed integer value of the average current flow through the sense resistor. It is updated every second Units are mA

TimeToEmpty(0x16/0x17)

This read-only function returns a unsigned integer value of the predicted remaining battery life if the present rate of discharge continues. A value of 65,535 indicates battery is not being discharged.

TimeToFull(0x18/0x19)

This read-only function returns a unsigned integer value of predicted remaining time until the battery reaches full charge in minutes based on *AverageCurrent*. The computation accounts for the taper current time extension from the linear TT computation based on fixed *AverageCurrent* rate of charge accumulation. A value of 65,535 indicates the battery is not being charged.

StandbyCurrent(0x1a/0x1b)

This read-only function returns a signed integer value of the measured standby current through the sense resistor. The *StandbyCurrent* is a adaptive measurement. Initially reports the standby current programmed in *InitialStandby* and after spending some time reports the measured standby current.

The register values are updated every second when the measured current is above the *Deadband* current and less than or equal to *InitialStandby*. The first two values that meet this criteria are averaged, since they may be stable values for approximately 4-minute constant, each new value is computed by taking approximately 93% weight of the standby current and approximately 7% of the current measured average current.

StandbyTimeToEmpty(0x1c/0x1d)

This read-only function returns a unsigned integer value of the predicted remaining battery life if the standby rate of discharge continues. The computation uses *NominalAvailableCapacity* (NAC) the uncompensated remaining capacity of this computation. A value of 65,535 indicates battery is not being discharged.

MaxLoadCurrent(0x1e/0x1f)

This read-only function returns a signed integer value in units of the maximum load conditions. The *MaxLoadCurrent* is a adaptive measurement which initially reports the maximum load current programmed in *InitialMaxLoadCurrent*. The measured current is greater than *InitialMaxLoadCurrent*, then *MaxLoadCurrent* is updated to the new current. *MaxLoadCurrent* is reduced to the average of the previous value and *InitialMaxLoadCurrent* whenever the battery is charged fully after previous discharge to a SOC less than 50%. This prevents the reported value from maintaining an unusually high value.

MaxLoadTimeToEmpty(0x20/0x21)

This read-only function returns an unsigned integer value of the predicted remaining battery life at the maximum load current discharge rate in minutes. A value of 65,535 indicates that the battery is not being discharged.

AvailableEnergy(0x22/0x23)

This read-only function returns an unsigned integer value of the predicted charge energy remaining in the battery. The values are reported in units of mWh.

AveragePower(0x24/0x25)

This read-only function returns a signed integer value of average power during battery charging and discharging. It is negative during discharge and positive during charge. A value of 0 indicates that the battery is not being discharged or charged. The values are reported in units of mW.

TimeToEmptyAtConstantPower(0x26/0x27)

This read-only function returns an unsigned integer value of the predicted remaining operating time if the battery is discharged at the *AveragePower* value in minutes. A value of 65,535 indicates that the battery is fully charged. The fuel gauge automatically updates *TimeToEmptyatContantPower* based on the *AveragePower* value every 1s.

CycleCount(0x2a/0x2b)

This read-only function returns an unsigned integer value of the number of cycles the battery has experienced with a range of 0 to 65,535. One cycle occurs when accumulated discharge $\geq CThreshold$.

StateOfCharge(0x2c/0x2d)

This read-only function returns an unsigned integer value of the predicted remaining battery capacity expressed as a percentage of *FullChargeCapacity* with a range of 0 to 100%.

Extended Data Commands

Extended commands offer additional functionality beyond the standard set of commands. They are used in the same manner, however, unlike standard commands, extended commands are limited to 2-byte words. The number of commands bytes to give extended command changes size from single to multiple bytes as specified in [Table 5](#). For details on the SEALED and UNSEALED states see Section [Access Modes](#).

Table 5. Extended Commands

NAME		COMMAND	ADDRESS	ACCESS ⁽¹⁾⁽²⁾	ACCESS ⁽¹⁾⁽²⁾
Reserved	RSVD	0x34...0x3b	N/A	R	R
<i>DesignCapacity</i>	DCAP	0x3c/0x3d	mAh	R	R
<i>DataFlashClass</i> ⁽²⁾	DFCLS	0x3e	N/A	N/A	R/W
<i>DataFlashBlock</i> ⁽²⁾	DFBLK	0x3f	N/A	R/W	R/W
<i>Authenticate</i> / <i>BlockData</i>	A/DF	0x40...0x53	N/A	R/W	R/W
<i>AuthenticateChecksum</i> / <i>BlockData</i>	ACKS/DFD	0x54	N/A	R/W	R/W
<i>BlockData</i>	DFD	0x55...0x5f	N/A	R	R/W
<i>BlockDataChecksum</i>	DFDCKS	0x60	N/A	R/W	R/W
<i>BlockDataControl</i>	DFDCNTL	0x61	N/A	N/A	R/W
<i>DeviceNameLength</i>	DNAMELEN	0x62	N/A	R	R
<i>DeviceName</i>	DNAME	0x63...0x69	N/A	R	R
<i>ApplicationStatus</i>	APPSTAT	0x6a	N/A	R	R
Reserved	RSVD	0x6b...0x7f	N/A	R	R

SEALED and UNSEALED states are entered via command **Control** 0x00/0x01.
 SEALED mode data flash CANNOT be accessed through commands 0x3e and 0x3f.

***DesignCapacity* 0x3c/0x3d**

SEALED and UNSEALED Access: This command returns the value in **DesignCapacity** and is expressed in mAh. This is intended to be the theoretical nominal capacity of the pack, based on the operation of the gauge functionality.

***DataFlashClass* 0x3e**

UNSEALED Access: This command sets the data flash class to be accessed. The class to be accessed should be entered in hexadecimal.
 SEALED Access: This command is not available in SEALED mode.

***DataFlashBlock* 0x3f**

UNSEALED Access: This command sets the data flash block to be accessed. When 0x00 is written, *BlockDataControl*, *DataFlashBlock* holds the block number of the data flash to be read or written. Example: writing 0x00 to *DataFlashBlock* specifies access to the first 32-byte block and 0x01 specifies access to the second 32-byte block and so on.

SEALED Access: This command directs which data flash block will be accessed by the *BlockData* command. Writing 0x00 to *DataFlashBlock* specifies the *BlockData* command will transfer authentication data issuing 0x01/0x02/0x03 instructs the *BlockData* command to transfer **ManufacturerInfoBlockA**, **ManufacturerInfoBlockB**, or **C**, respectively.

***BlockData* 0x40...0x5f**

UNSEALED Access: This data block is the remainder of the 32-byte data block when accessing data flash.

SEALED Access: This data block is the remainder of the 32-byte data block when accessing **ManufacturerInfoBlockA**, **ManufacturerInfoBlockB**, or **C**.

BlockDataChecksum{0x60

UNSEALED Access This byte contains the checksum of the 32 bytes of block data read or written to data flash. The least-significant byte of the sum of the data bytes written must be complemented (255 - least-significant byte) before being written to 0x60.

for x the

SEALED Access This byte contains the checksum of the 32 bytes of block data written to **BlockA**, **B**, or **C**. The least-significant byte of the sum of the data bytes written must be complemented (255 - x) for x the least-significant byte) before being written to 0x60.

ManufactureInfo

BlockDataControl{0x61

UNSEALED Access This command is used to control data flash access. Writing 0x00 to this command enables *BlockData* access general data flash. Writing 0x01 to this command enables SEALED mode operation of *DataFlashBlock*.

SEALED Access This command is not available in SEALED mode.

DeviceNameLength{0x62

UNSEALED and SEALED Access This byte contains the length of the **DeviceName**.

DeviceName{0x63...0x69

UNSEALED and SEALED Access This block contains the device name that is programmed in **DeviceName**.

ApplicationStatus{0x6a

This byte function allows the system to read the bq27510 **ApplicationStatus** data flash location. Refer to [Table 6](#) for specific bit definitions.

Reserved{0x6b-0x7f

DATA FLASH INTERFACE

Accessing Data Flash

The bq27510 data flash is non-volatile memory that contains bq27510 initialization default status, calibration, configuration, and sensor information. The data flash can be accessed in several different ways, depending on what mode the bq27510 is operating in and what data is being accessed.

Commonly accessed data flash memory locations frequently read by a system are conveniently accessed through specific instructions already described in [Section 6.4.1](#), *Data Commands*. These commands are available when the bq27510 is in either UNSEALED or SEALED modes.

Most data flash locations, however, are only accessible in UNSEALED mode by use of the bq27510 evaluation software data flash block transfer. These locations should be optimized and/or fixed during the development and manufacturing processes. They become part of the image file and can then be written to multiple battery packs. Once established, the values generally remain unchanged during end-equipment operation.

To access data flash locations individually, the block containing the desired data flash location(s) must be transferred to the command register locations where they can be read or the system changed directly. This is accomplished by sending the set-up command *BlockDataControl* (0x61) with data 0x00. Up to 32 bytes of data can be read directly from the *BlockData* (0x40...0x5f) externally altered, then rewritten to the *BlockData* command space. Alternatively, specific locations can be read or altered and rewritten if their corresponding offsets are set in the *BlockData* command space. Finally, the data residing in the command space is transferred to data flash on the correct checksum for the whole block is written to *BlockDataChecksum* (0x60).

Occasionally, a data flash CLASS will be larger than the 32-byte block size. In this case, the command sets the address of the 32-byte block desired to be read. The correct command address is given by $0x40 \text{ offset} \text{ modulo } 32$. For example, access the Gauging class, *DataFlashClass*, issued $0x050$ to set the class. Because the offset is 8, it must reside in the second 32-byte block. Hence, *DataFlashBlock* issued $0x01$ to set the block offset and the offset used to index into the *BlockData* memory area is $0x4048 \text{ modulo } 32 = 0x4048 - 0x4040 = 0x08$.

Reading and writing subclass data are block operations up to 32 bytes in length. If the data length exceeds the maximum block size, the data is ignored.

None of the data written to memory are bounded by the bq27510; the values are not rejected by the gauge. Writing incorrect values may result in hardware failure due to firmware program interpretation of the invalid data. The written data is persistent; a power-on reset does not solve the fault.

MANUFACTURER INFORMATION BLOCKS

The bq27510 contains 96 bytes of programmable data flash storage: *ManufactureInfBlockA*, *ManufactureInfBlockB*, *ManufactureInfBlockC*. The method of accessing these memory locations is slightly different depending on whether the device is UNSEALED or SEALED nodes.

When in UNSEALED mode and where $0x00$ has been written to *BlockDataControl*, accessing the Manufacturer Information Blocks is identical to accessing general data flash locations. First, a *DataFlashClass* command is used to set the subclass, then a *DataFlashBlock* command sets the offset to the first data flash address within the subclass. The *BlockData* command codes contain the referenced data flash data. When writing the data flash, a checksum is expected to be received by *BlockDataChecksum*. Only when the checksum is received and verified, the data is actually written to data flash.

As an example, the data flash location for *ManufactureInfBlockB* is defined as having subclass 5 and an offset of 2 through 6 (32-byte block). The specification of Class System Data is needed to address *ManufactureInfBlockB* used instead of grouping purposes when viewing data flash info for the bq27510 evaluation software.

When in SEALED mode where $0x01$ *BlockDataControl* does not contain $0x00$, data flash is no longer available. The unsealed UNSEALED mode. Rather than issuing subclass information designated Manufacturer Information Blocks selected with the *DataFlashBlock* command, issuing $0x010x020x03$ with this command causes the corresponding information block (A, B, or C, respectively) to be transferred to the command space $0x40 \dots 0x56$. Reading is done by system upon successful writing of checksum information to *BlockDataChecksum*, the modified block is returned to data flash.

BlockA is read-only when in SEALED mode.

Note: ManufactureInfo

ACCESS MODES

The bq27510 provides three security modes (FULL ACCESS, UNSEALED, and SEALED) that control data flash access permissions according to [Table 6](#). Data flash locations specified in [Table 7](#) are accessible to the user. Manufacturer information refers to the three reserved 32-byte blocks.

Table 6. Data Flash Access

Security Mode	Data Flash	Manufacturer Information
FULL ACCESS	R/W	R/W
UNSEALED	R/W	R/W
SEALED	None	R(A)R/W(BC)

Although FULL-ACCESS and UNSEALED nodes appear identical, only FULL-ACCESS allows the bq27510 to write access-mode transition keys.

SEALING/UNSEALING DATA FLASH

The bq27510 implements key-access schemes to transition between SEALED/UNSEALED and FULL-ACCESS nodes. Each transition requires that a unique set of keys be sent to the bq27510 via the *Control* register. The keys must be sent consecutively with the data being written to the *Control* register. Note that to avoid conflict, the keys must be different from the codes presented in the *CNT/IDATA* column of [Table 2](#) subcommands.

When in SEALED mode, the *[SS]* bit of *CONTROL_STATUS* is set, but when the UNSEAL keys are correctly received by the bq27510, the *[SS]* bit is cleared. When the full-access keys are correctly received, the *CONTROL_STATUS [FAS]* bit is cleared.

Both sets of keys are each 4 bytes each in length and are stored in data flash. The UNSEAL key (stored at *UnseaKey0* and *UnseaKey1*) and the FULL-ACCESS key stored at *FulAccessKey0* and *FullAccessKey1* can only be updated when in FULL-ACCESS mode. The order of bytes entered through the *Control* register is the reverse of what is read from the part. For example, if *UnseaKey0* returns 0x1234 and 0x5678, then *Control* should supply 0x3412 and 0x7856 to unseal the part.

DATAFLASHSUMMARY

Table summarizes the data locations available in these including the default, minimum and maximum values.

Table DataFlash Summary

SubclassID	Subclass	Offset	Initial Value	Default Value	Write Type	Min Value	Max Value	Unit
Configuration	Safety	OTChg 0	1200	0	I2		550	0.1°C
Configuration	Safety	OTChg 2me	0		U1	60	2	s
Configuration	Safety	OTChg Recovery	1200	0	I2		500	0.1°C
Configuration	Safety	ODsg 5	1200	0	I2		600	0.1°C
Configuration	Safety	ODsg 7me	0		U1	60	2	s
Configuration	Safety	ODsg Recovery	1200	0	I2		550	0.1°C
Charge/Discharge		Charge/Discharge	1200	400	I2		0	0.1°C
Charge/Discharge		Charge/Discharge	1200	400	I2		450	0.1°C
Charge/Discharge		Temp Hys	0		I2	100	50	0.1°C
Configuration	Charge	Charge Voltage	4200	2000	0	I2		mV
Configuration	Charge	Delta Temperature	0		I2	500	50	0.1°C
Configuration	Charge	Suspend Temperature Low	2000	2000	0	I2		-50
Configuration	Charge	Suspend Temperature High	2000	2000	0	I2		550
Configuration	Charge Termination	Tape Current	1000	0	I2		100	mA
Configuration	Charge	Minimum Tape Charge	1000	0	I2		0.01mA	25
Configuration	Charge Termination	Tape Voltage	1000	0	I2		100	mV
Configuration	Charge Termination	Current Tape Window	0		U1	60	40	s
Configuration	Data	Initial Standby Current	0	-128	11			-10
Configuration	Data	Initial Max Load Current	0	-32,767	7			-500
Configuration	Data	CC Threshold	900	32,767	0	I2		mAh
Configuration	Data	Design Capacity	1000	5,535	0	I2		mAh
Configuration	Data	Device Name	x	S8				- bq27510 x
Configuration	Discharge	SOC Set threshold	0		11		255	150
Configuration	Discharge	SOC Clear threshold	0		11		255	175
Configuration	Discharge	SOC Set threshold	0		11		255	75
Configuration	Discharge	SOC Clear threshold	0		11		255	100
SystemData	Manufacture Info	BC[30-31]	0xff	0x00	H1			0x00
SystemData	Manufacture Info	BC[30-31]	0xff	0x00	H1			0x00
SystemData	Manufacture Info	BC[30-31]	0xff	0x00	H1			0x00
Configuration	Registers	Operate Configuration	0x09	79x000				
Configuration	Power	Flash Update Voltage	2800	4200	0	I2		mV
Configuration	Power	Sleep Current	0		I2	100	10	mA
Configuration	Power	Hibernate Current	0		U2	700	8	mA
Configuration	Power	Hibernate Voltage	2550	3000	2400	U2		mV
Configuration	ITCg	Load Select	0		U1	255	1	-
Configuration	ITCg	Load Mode	0		U1	255	0	-
Configuration	ITCg	Term Voltage	3050	32,767	7			mV
Configuration	ITCg	Use Rate-mA	9000	0	I2		0	mA
Configuration	ITCg	Use Rate-mW	14,000	0	I2		0	mW
Configuration	ITCg	Reserve Cap-mAh	9000	0	I2		0	mAh
Configuration	ITCg	Reserve Cap-mWh	14,000	0	I2		0	mWh
Configuration	Current Thresholds	Dsg Current Threshold	2000	0	I2		60	mA
Configuration	Current Thresholds	Chg Current Threshold	2000	0	I2		75	mA
Configuration	Current Thresholds	Qui Current	1000	0	I2		40	mA
Configuration	Current Thresholds	Dsg Relx Time	1800	8191	0	U2		s
Configuration	Current Thresholds	Chg Relx Time	0		U1	255	60	s
Configuration	Current Thresholds	Qui Relx Time	0		U1	63	1	s

Table 7. Data Flash Summary (continued)

SubclassID	Subclass	Offset	Initial Value	Default Value	Write				
0000	State	IEEnable	0xff	0x00	H1			0x00	
0000	State	ApplicationStatus	0xff	0x00	H1			0x00	
0000	State	Qmax 2	10002,767	0	I2			mAh	
0000	State	CycleCount0	65,535	0	U2			0	
0000	State	UpdateStatus0	0x03	0x00	H1			0x00	
0000	State	Qmax 1	10002,767	0	I2			mAh	
0000	State	CycleCount1	65,535	0	U2			0	
0000	State	UpdateStatus1	0x03	0x00	H1			0x00	
0000	State	AvgRateRun	-2992,767					mA	
0000	State	AvgRateRun	mAh -132,767						
Default Tables	DeRa	See 18	(1)						
Default Tables	DeRa	0-18							
Rate Tables	91	PackRa	See 18	(1)					
Rate Tables	92	PackRa	0-18						
Rate Tables	93	PackRax	0-18						
Rate Tables	94	PackRax	0-18						
Calibration		Data	CCGain0	0.1	F4		4	0.47095	-
Calibration		Data	CCDelta	2196.8	0.4638				
Calibration		Data	CCOffset	-1662.767					mV
Calibration		Data	BoardOffset	127	-128	I1		0	mV
Calibration		Data	IntTempOffset	127	-128	I1		78	0.1°C
Calibration		Data	ExtTempOffset	127	-128	I1		0	0.1°C
Calibration		Data	PackOffset	127	-128	I1		0	mV
Calibration		Current	Deadband	0	U1		255	5	mA
Security	112	Codes	UnsealKey0	0x3672	0x00				-
Security	112	Codes	UnsealKey1	0x0413	0x00				-
Security	112	Codes	Full-AcctesKey0	0x00				0xffff	-
Security	112	Codes	Full-AcctesKey1	0x00				0xffff	-

(1) Encoded battery profile information created by bqEasy software.

FUNCTIONAL DESCRIPTION

FUEL GAUGING

The bq27510 measures the cell voltage, temperature, and current to determine battery SOC. The bq27510 monitors charge and discharge activity by sensing the voltage across small-value resistors (5nΩ to 20mΩ typ.) between the SRP and SRN pins and is series with the cell. By integrating charge passing through the battery, the battery's SOC is adjusted during battery charge or discharge.

The total battery capacity is found by comparing states of charge before and after applying the load with the amount of charge passed. When an application load is applied, the impedance of the cell is measured by comparing the SOC obtained from a predefined function to present SOC with the measured voltage under load. Measurements of DC voltage and charge integration determine chemical state of charge and chemical capacity (Qmax). The initial Qmax values are taken from the manufacturer's data sheet, multiplied by the number of parallel cells, and set to the value **DesignCapacity**. The bq27510 acquires and updates the battery-impedance profile during normal battery usage. It uses this profile along with SOC and the Qmax value to determine **FullChargeCapacity** and **StateOfCharge** specifically for the present load and temperature. **FullChargeCapacity** is reported as capacity available from a fully charged battery under the present load and temperature until **Voltage** reaches the **TermVoltage**. **NominalAvailableCapacity** and **FullAvailableCapacity** are then compensated for load variations of **RemainingCapacity** and **FullChargeCapacity** respectively.

The bq27510 has two flags accessed by the **Flags** function that warn when the battery's SOC has fallen to critical levels. When **RemainingCapacity** falls below the first capacity threshold, specified in **SOCSetThreshold**, the **[SOC1]** (State of Charge Initial) flag is set. The flag is cleared once **RemainingCapacity** rises above **SOCSetThreshold**. The bq27510's BAT_LOV pin automatically reflects the status of the **[SOC1]** flag. All units are in mAh.

When **RemainingCapacity** falls below the second capacity threshold, **SOCSetThreshold**, the **[SOCF]** (State of Charge Final) flag is set, serving as a final discharge warning if **SOCSetThreshold = 1** the flag is inoperative during discharge. Similarly when **RemainingCapacity** rises above **SOCClearThreshold** and the **[SOCF]** flag has already been set, the **[SOCF]** flag is cleared. All units are in mAh.

IMPEDANCE TRACK™ VARIABLES

The bq27510 has several data flash variables that permit the user to customize the Impedance Track™ algorithm for optimized performance. These variables are dependent upon the power characteristics of the application as well as the cell itself.

LoadMode

LoadMode is set to select either the constant-current or constant-power mode for the Impedance Track™ algorithm as seen in **LoadSelect** (see **LoadSelect**). When **LoadMode** is the **ConstantCurrentModel** is used (default) when the **ConstantPowerModel** is used. The **[LDMD]** bit of CONTROL_STATUS reflects the status of **LoadMode**.

LoadSelect

LoadSelect defines the type of power or current model to be used to compute load-compensated capacity in the Impedance Track™ algorithm. If **LoadMode = ConstantCurrent**, then the options presented in **Table 8** are available.

Table 8. Constant-Current Mode Used When LoadMode = 0

LoadSelect Value	Current Mode Used
0	Average discharge current from previous cycle. There is an internal register that records the average discharge current through each entire discharge cycle. The previous average is stored in this register.
1 (default)	Present average discharge current. This is the average discharge current from the beginning of this discharge cycle until present time.
2	Average current based on the AverageCurrent
3	Current based on a low-pass-filtered version of AverageCurrent (τ=14s)

Table 8. Constant-Current Mode Used When Load Mode 0 (continued)

Load Select Value	Current Mode Used
4	Design capacity (CR) based on Design Capacity (500) in mA.
5	At Rate (mA) Use whatever current is AtRateI
6	User_Rate-mA Use the value in User_RateI . This gives a completely user-configurable method.

If Load Mode 0 (Constant Power) then the following options are available:

Table 9. Constant-Current Mode Used When Load Mode 1

Load Select Value	Current Mode Used
0 (default)	Average discharge current from previous cycle. There is an internal register that records the average discharge current through each entire discharge cycle. The previous average is stored in this register.
1	Present average discharge current. This is the average discharge current from the beginning of this discharge cycle until present time.
2	Average current (voltage based) of the AverageCurrentI and VoltageI .
3	Current (voltage based) of low-pass-filtered version of AverageCurrentI ($\tau=14s$) and VoltageI .
4	Design energy (CR) based on Design Energy (500) in mA.
5	At Rate (10mW) Use whatever current is AtRateI
6	User_Rate-10mW Use the value in User_RateI mW. This gives a completely user-configurable method.

ReserveCap-mAh

ReserveCap-mAh determines how much actual main capacity exists before **RemainingCapacityI** is reached. A no-load rate of compensation is applied to this reserve.

ReserveCap-mWh

ReserveCap-mWh determines how much actual remaining capacity exists after reaching **AvailableEnergyI**, before **TerminateVoltage** is reached. A no-load rate of compensation is applied to this reserve capacity.

DsgCurrentThreshold

This register is used as a threshold by many functions in the bq27510 to determine actual discharge currents flowing out of the cell. The threshold should be set low enough to be below any normal application load current but high enough to prevent noise or drift from affecting the measurement.

ChgCurrentThreshold

This register is used as a threshold by many functions in the bq27510 to determine actual charge currents flowing into the cell. The threshold should be set low enough to be below any normal charge current but high enough to prevent noise or drift from affecting the measurement.

QuiCurrent, DsgRelaxTime, ChgRelaxTime and QuiRelaxTime

The **QuiCurrent** is used as part of the impedance track™ algorithm to determine whether the bq27510 enters relaxation mode from a current flowing mode in either the charge direction or the discharge direction. The value of **QuiCurrent** should be above the standby current of the system.

The following criteria must be met to enter relaxation mode:

$$|AverageCurrentI| < QuiCurrent \text{ for } DsgRelaxTime \text{ (if CHG mode) } ChgRelaxTime \text{ (if DSG mode)}$$

After about 30 minutes in relaxation mode, the bq27510 attempts to take accurate OC readings. An additional requirement of $dV/dt = \mu V/sec$ is required for the bq27510 to perform OC max updates. These updates are used in the impedance track™ algorithm. It is critical that the battery voltage be relaxed during OC readings and that the current is not higher than C/20 when attempting to go to relaxation mode.

QuitRelaxTime specifies the minimum time required for AverageCurrent to remain above the QuitCurrent threshold before exiting relaxation mode.

Qmax and Qmax1

Generically called Qmax, these dynamic variables contain the respective maximum chemical capacity of the active cell profiles and are determined by comparing states of charge before and after applying the load with the amount of charge passed. They also correspond to capacity at very low rates of discharge such as C/20 rate. For high accuracy, this value is periodically updated by the bq27510 during operation. Based on the battery cell capacity information, the initial value of chemical capacity should be entered in the Qmax field of each default cell profile. The ImpedanceTrack™ algorithm updates these values and maintains them in the associated actual cell profiles.

UpdateStatus0 UpdateStatus1

Bit(0x01) of the UpdateStatus registers indicates that the bq27510 has learned the Qmax parameters and is accurate. The remaining bits are reserved. Bit 0 status flag that can be set by the bq27510. Although a user can modify Bit 0, it should be modified only when creating golden image files as explained in the application note Preparing Optimized Default Flash Constants for Specific Battery Types (SLUA334). Bit 0 is updated as needed by the bq27510.

AvgLasRun

The bq27510 logs the current averaged from the beginning to the end of each discharge cycle. It stores this average current from the previous discharge cycle in this register. This register should never be modified. It is only updated by the bq27510 when required.

AvgLasRun

The bq27510 logs the power averaged from the beginning to the end of each discharge cycle. It stores this average power from the previous discharge cycle in this register. To get an accurate average power reading, the bq27510 continuously multiplies instantaneous current times Voltage to get power. It logs this data to derive the average power. This register should never be modified. It is only updated by the bq27510 when required.

DeltaVoltage

The bq27510 stores the maximum difference of Voltage during hot bad spike and dorm bad spike. The ImpedanceTrack™ algorithm calculates remaining capacity for pulse bad spike. It is recommended to change this value.

DefaultRanRTables

These tables contain encoded data and, with the exception of the DefaultRTables, are automatically updated during device operation. No changes should be made except for reading/writing the values from a pre-learned pack (part of the process of creating golden image files).

DETAILED PIN DESCRIPTIONS

The Operator Configuration Register

Some bq27510 pins are configured via the Operator Configuration data flash registers as indicated in Table 5. This register is programmed/read via the methods described in Section Accessing the Data Flash. The register is located at subclass=64 offset=0.

Table 00 Operator Configuration Bit Definition

Table with 9 columns: bit7, bit6, bit5, bit4, bit3, bit2, bit1, bit0. Row 1: HIGH-Z, PUMP, PUMP, PUMP, PUMP, PUMP, PUMP, PUMP. Row 2: PUMP, PUMP, PUMP, PUMP, PUMP, PUMP, PUMP, PUMP.

RESCAP	No-load data compensation is applied to the reserve capacity calculation. True when set Defaults.
BAT_GD	Override bit if the gauge enters HIBERNATE. Only due to the cell voltage. BAT_GD will not
BATG_OVR	Negate True when set Defaults. Both current and voltage are below the HIBERNATE threshold. The voltage condition check above precedes the current condition check.
PFC_CFG1/PFC_CFG0	Pir function code (PFC) mode selection. PFC0,1,0 selected by 0/00/1 or 1/0 respectively Defaults PFC(0/1).
IWAKE/RSNS1/RSNS0	These bits configure the current wake function (see Table 1) Defaults 0/0/1.
IDSELEN	Enables self-profile selection feature. True when set Defaults.
SLEEP	The fuel gauge enters sleep operating conditions allow. True when set Defaults.
RMFCGM	Updated with the value from FCC on valid charge termination. True when set Defaults.
BATL_PO	BAT_LOW pin active-high. True when set Defaults.
BATG_PO	BAT_LOW/BAT_GD pin active-low. True when cleared Defaults.
BAT_FN	Selects BAT_LOW (bit clear) or BAT_GD (bit set) function on pin 12 Defaults.
TEMP	Selects external thermistor for temperature measurements. True when set Defaults.

Pir Function Code Descriptions

The bq27510 has three possible pin-function variations that are selected in accordance with the circuit architecture of the end application. Each variation has been assigned a pir function code of PFC.

When the PFC is 0, only the bq27510 measures battery temperature and discharge and relaxation conditions. The charger does not receive any information from the bq27510 about the temperature readings and therefore operates open-loop with respect to battery temperature.

For PFC 1 and 2, except temperature is also monitored during battery charging. If charging temperature falls outside the range defined in the [Charge Inhibit](#) fo additional details.

Finally when the PFC is 2, the battery thermistor can be shared between the fuel gauge and the charger. The charger has full usage of the thermistor during battery charging while the fuel gauge uses the thermistor exclusively during discharge and battery relaxation.

The PFCs specified in [Operation Configuration \[PFC_CFG1 PFC_CFG0\]](#) The defaults PFC4.

BAT_LOW/BAT_GD pin

The BAT_LOW/BAT_GD pin is a multiplexed pin. The functions are defined by [\[BAT_FN\]](#) as a system process with an electrical indicator of battery status. The BAT_LOW function is activated, signaling on the multiplexed pin follows the status of the [\[SOC1\]](#) bit in the [Flags](#) register. Note that the polarity of the pin output can be inverted via the [\[BATL_POL\]](#) bit of the [Operation Configuration](#).

The bq27510 must operate in conjunction with the electronics system appliances such as chargers, other ICs and application circuits that draw appreciable power. After a battery is inserted into the system, there should be no charging or discharging current higher than C/20 so that an accurate OC can be read. The OC is used for helping determine which battery profile to use as it constitutes part of the battery impedance measurement.

When a battery is inserted into the system, the impedance Track™ algorithm requires that charging of the battery takes place and any discharge is limited to less than C/20—these conditions are sufficient for the fuel gauge to take an accurate OC reading. To disable these functions, the BAT_LOW/BAT_GD pin is merely negated from the default setting. Once an OC reading has been made, the BAT_LOW/BAT_GD pin is asserted, thereby enabling battery charging and regulated discharge of the battery. The [Operation Configuration \[BATG_POL\]](#) bit can be used to set the polarity of the battery good signals should the default configuration need to be changed.

In PFC 0, the BAT_LOW/BAT_GD pin is also used to disable battery charging when the bq27510 reads battery temperature outside the range defined by [\[ChargeInhibitTempLow ChargeInhibitTempHigh\]](#). The BAT_LOW/BAT_GD pin is returned to its default state once temperature falls within the range [\[ChargeInhibitTempLowTempHigh ChargeInhibitTempHighTempHigh\]](#).

Battery Detection using the BI/TOU Pin

During power-up or hibernation activities, any activity where the bq27510 needs to determine whether a battery is connected to the gauge applies to battery presence. First, the BI/TOU pin is pulled up to a high-Z status. The weak 1.8M Ω pull-up resistor will keep the pin high while a battery is present. When a battery is inserted or already inserted into the system device, the BI/TOU pin will be pulled down. This state is detected by the gauge which polls this pin every second when the gauge has power. A status is assumed when the bq27510 reads a thermistor voltage that is near 2.5V. battery-disconnected

TEMPERATURE MEASUREMENT

The bq27510 measures battery temperature via its input to determine battery temperature status information for the gauging algorithm and charger-control sections of the gauge. Alternatively, it also measures internal temperature via on-chip temperature sensors. [TEMPS] bit Operation Configuration registers cleared.

Regardless of which sensor is used for temperature measurement, system processors are requested to request the current battery temperature by calling the `Temperature()` function (see Section [Standard Commands](#) for specific information).

The external temperature measurement circuit uses a 03AT-type thermistor. Additional circuit information for connecting this thermistor to the bq27510 is shown in Section [Reference Schematic](#).

OVER-TEMPERATURE INDICATION

Over-Temperature Charge

During charging, `Temperature()` reaches the threshold of `OChg` for a period of `OChgTime` and `AverageCurrent() > ChgCurrentThreshold`, then the `[OTC]` bit of `Flags` is set. When `Temperature()` falls to `OChgRecovery`, the `[OTC]` of `Flags` is reset.

If `OChgTime` = 0, the feature is completely disabled.

Over-Temperature Discharge

During discharging, `Temperature()` reaches the threshold of `ODsg` for a period of `ODsgTime` and `AverageCurrent() ≤ -DsgCurrentThreshold`, then the `[OTD]` bit of `Flags` is set. When `Temperature()` falls to `ODsgRecovery`, the `[OTD]` of `Flags` is reset.

If `ODsgTime` = 0, the feature is completely disabled.

CHARGING AND CHARGE-TERMINATION INDICATORS

Detecting Charge Termination

For proper bq27510 operation, the cell charging voltage must be specified by the user. The default value of this variable is `ChargingVoltage` = 4200mV.

The bq27510 detects charge termination when (1) during consecutive periods of `CurrentTapeWindow`, the `AverageCurrent()` is `TapeCurrent`, (2) during the same periods, the accumulated charge capacity `MinTapeCharge` `CurrentTapeWindow` and (3) `Voltage() > ChargingVoltageTapeVoltage`. When this occurs, the `[CHG]` bit of `Flags` is cleared. Also, the `[RMFCC]` bit of `Operation Configuration` is set and `RemainingCapacity()` is equal to `FullChargeCapacity()`.

Charge Inhibit and Suspend

The bq27510 indicates when the battery temperature falls below or rises above predefined thresholds `ChargeInhibitTempLow` or `ChargeInhibitTempHigh`, respectively. In this mode, the `CHG_INT` pin is set and the `BAT_GD` pin is asserted to indicate this condition. The `CHG_INT` pin is cleared and the `BAT_GD` pin is asserted once the battery temperature returns to the range `[ChargeInhibitTempLowTempHysChargeInhibitTempHighTempHys]`.

When PFG1 of the bq27510 indicates whether battery temperature has fallen below or risen above predefined thresholds **SuspendLowTemp** or **SuspendHighTemp**, respectively. This node, the EXCHG bit, also indicates this condition. The EXCHG bit is cleared once the battery temperature returns to the range **InhibitTempLowTempHys** **ChargeInhibitTempHighTempHys**.

[Charge

The charging should start when the temperature is below the ChargeInhibitTempLow above the ChargeInhibitTempHigh. The charging can continue if the charging starts inside the window [ChargeInhibitTempLow, ChargeInhibitTempHigh] until the temperature is either below SuspendLowTemp or above SuspendLowTemp. Therefore, the window [ChargeInhibitTempLow, ChargeInhibitTempHigh] must be inside the window of [SuspendLowTemp, SuspendHighTemp].

POWERMODES

The bq27510 has four power modes: NORMAL, SLEEP, HIBERNATE, and BATINSERTCHECK. In NORMAL mode, the bq27510 is fully powered and can execute any allowable task. In SLEEP mode, the fuel gauge exists in a reduced-power state periodically taking measurements and performing calculations. In HIBERNATE mode, the fuel gauge is in a very low-power state but can be woken up by communication. Finally, the BATINSERTCHECK mode is a powered-up but low-power halted state where the bq27510 resides when a battery is inserted into the system.

The relationship between these modes is shown in [Figure 2](#).

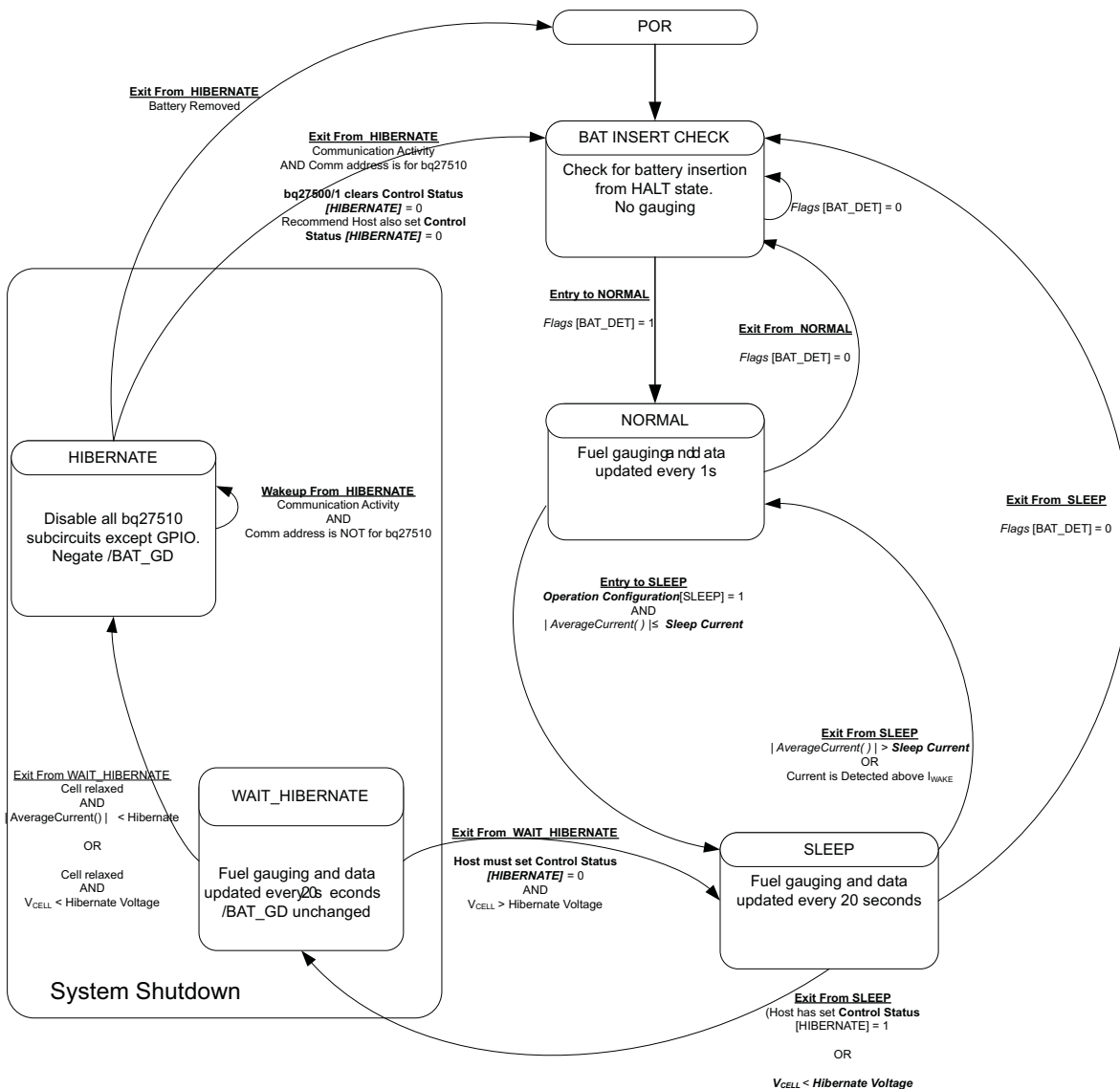


Figure 2 Power Mode Diagram

NORMAL Mode

The bq27510 enters NORMAL Mode when in any of the power modes. During this mode, fuel gauging is enabled and the bq27510 performs SAR ADC auto calibration to minimize offset. Decisions to change states are also made. This mode is exited by activating a different power mode.

AverageCurrent(),

Because the gauge consumes the most power in NORMAL mode, the impedance track™ algorithm minimizes the time the gauge remains in this mode.

SLEEP Mode

SLEEP Mode is entered automatically if the feature is enabled. The bq27510 enters SLEEP Mode when *AverageCurrent()* is below the programmable level *Sleep Current*. Once in SLEEP Mode, the bq27510 performs SAR ADC auto calibration to minimize offset.

During SLEEP Mode, the bq27510 periodically takes data measurements and updates its data set. However, a majority of times, the bq27510 is in a high impedance condition.

The bq27510 exits SLEEP mode when any of the following conditions are met: (1) *Average Current* rises above *Sleep Current* (2) current excess of *WAKE* through *RSENSE* is detected.

In the event the battery is removed from the system while charging is present (and powering the gauge), Impedance Track™ updates are not necessary. Hence the gauge enters state that checks for battery insertion and does not continue executing the impedance Track™ algorithm.

BATINSERTCHECK Mode

This mode is a halted-CPU state that occurs when an adapter or other power source is present to power the bq27510 (and system) yet a battery has been detected. When battery insertion is detected, a brief initialization activity begins which includes OC measurement setting the BAT_GPI and selecting the appropriate battery profiles. The battery insertion detection takes about 8ms.

Some commands issued by system processor can be processed while the bq27510 is halted in this mode. The gauge will wake up to process the command then return to the halted state awaiting battery insertion.

HIBERNATE Mode

HIBERNATE mode should be used when the system equipment needs to enter a low-power state and minimal gauge power consumption is required. This mode is ideal when system equipment is its own HIBERNATE SHUTDOWN or OFF mode. The gauge enters HIBERNATE mode if the low cell voltage or low load current.

- HIBERNATE due to cell voltage: When the cell voltage drops below the hibernate voltage and a valid OC measurement has been taken, the gauge enters HIBERNATE mode. The HIBERNATE bit of the CONTROL register has no impact on the gauge or the HIBERNATE mode.
- HIBERNATE due to load current: If the gauge enters the HIBERNATE mode due to load current, the HIBERNATE bit of the CONTROL_STATUS register must be set. The gauge waits until the HIBERNATE mode until a valid OC measurement and the magnitude of the average cell current has fallen below *Hibernate Current*.

The gauge will remain in HIBERNATE mode until the system issues a *WAKE* command. The gauge can be woken by POR or *WAKE* communication that is not directed to the gauge. The gauge will wake the gauge at least every long).

During hibernate mode the BAT_GPI signal is gated (to battery charging/discharging). This prevents a charge application from inadvertently charging the battery before a OC reading is taken. It is the system's responsibility to wake the bq27510 after it has gone to HIBERNATE mode. After waking the gauge can proceed with the initialization of the battery information (OCV profiles selection etc.)

It is suggested to keep the system in SLEEP mode instead of HIBERNATE mode when a charge is attached. The reason is that charger removal will wake up the battery from HIBERNATE mode.

POWER CONTROL

Reset Functions

When the bq27510 detects a software reset (*[RESET] bit of Control* initiated) it determines the type of reset and increments the corresponding counter. This information is accessible by issuing the *Control* function with the *RESET_DATA* subcommand.

As shown in [Figure 6](#), if a partial reset was detected, RAM checksums generated and compared against the previously stored checksum. If the checksum values do not match, the RAM is initialized (a *Full Reset*). The stored checksums are updated every time RAM is altered.

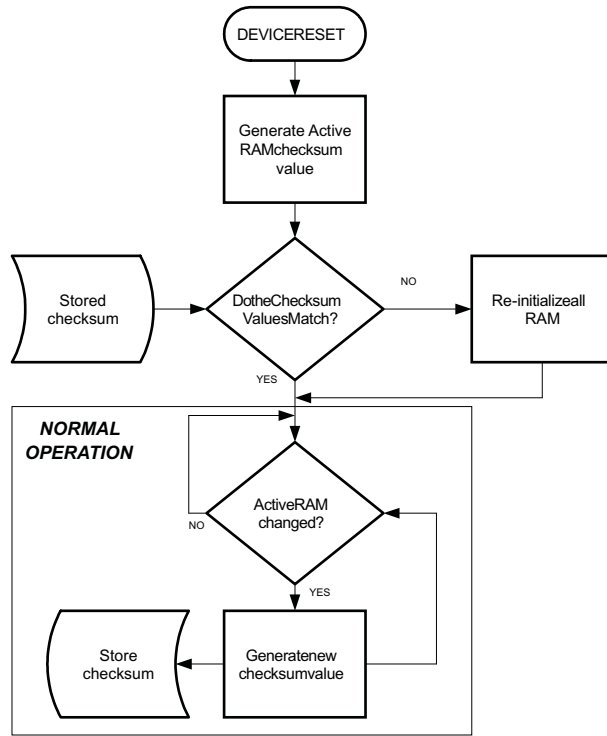


Figure 8 Partial Reset Flow Diagram

Wake-Up Comparator

The wake-up comparator is used to indicate a change in current while the bq27510 is in SLEEP mode.

Operation Configuration uses bits [RSNS1–RSNS0] to select sense resistor selection. **Configuration** also uses the [IWAKE] bit to select one of two possible voltage threshold ranges for the sense resistor selection. An interrupt is generated when the threshold is breached in either charge or discharge directions. Setting both [RSNS1] and [RSNS0] to 0 disables this feature.

Operation

Table 11 WAKE Threshold Settings ⁽¹⁾

RSNS1	RSNS0	IWAKE	Vth(SRP-SRN)
0	0	0	Disabled
0	0	1	Disabled
0	1	0	+10mV or -1.0mV
0	1	1	+2.2mV or -2.2mV
1	0	0	+2.2mV or -2.2mV
1	0	1	+4.6mV or -4.6mV
1	1	0	+4.6mV or -4.6mV
1	1	1	+9.8mV or -9.8mV

⁽¹⁾The actual resistance value versus the setting of the sense resistors is not important; just the actual voltage threshold when calculating the configuration. The voltage thresholds are typical values under room temperature.

Flash Updates

Data Flash can only be updated if $V_{DD} \geq \text{FlashUpdateOKVoltage}$. Flash programming current can cause an increase in LDO dropout. The value of $\text{FlashUpdateOKVoltage}$ should be selected such that the bq27510 V_{CC} voltage does not fall below its minimum of 2.4V during Flash write operations.

AUTOCALIBRATION

The bq27510 provides an autocalibration feature that will measure the voltage offset across SRP and SRN from time-to-time as operating conditions change and subtract the resulting offset from normal sense resistor voltage (VSR) for maximum measurement accuracy.

Autocalibration of the ADC begins on entry to SLEEP mode except if $\text{Temperature} \leq -45^\circ\text{C}$.

$\text{Temperature} \leq 5^\circ\text{C}$ or $\text{Temperature} \geq 100^\circ\text{C}$

The fuel gauge also performs single offset when the condition of $\text{AverageCurrent} \leq 100\text{mA}$ (2) is met. Offset calibration is performed if $\text{VoltageChangeSinceOffsetCalibration} \geq 256\text{mV}$ or $\text{TemperatureChangeSinceOffsetCalibration} \geq 80^\circ\text{C}$ or $\text{Time} \geq 60\text{s}$.

Capacity and current measurements will continue to be measured during the offset calibration when these measurements cannot be performed. The battery voltage drops no more than 2mV during the offset calibration; the load current has likely increased considerably; hence the offset calibration will be aborted.

APPLICATION-SPECIFIC INFORMATION

BATTERY PROFILE STORAGE AND SELECTION

Common Profile Aspects

When battery packs are removed from system equipment that implements the bq27510, the fuel gauge maintains some of the battery information in case it is re-inserted. This way the impedance Track™ algorithm often has means of recovering battery-status information, thereby maintaining good state-of-charge (SOC) estimates.

The default battery profiles are available to store battery information. They are used to provide the impedance Track™ algorithm with the default information on the battery type expected to be used with the end-equipment. The default profiles can be used to support batteries of same chemistry but different capacities. Default profiles are programmed by the end-equipment manufacturer. Only one of the default profiles can be selected and this selection cannot be changed during end-equipment operation.

In addition to the default profiles, the bq27510 maintains two active profiles: Cell0 and Cell1 . These tables hold dynamic battery data and keep track of the status of up to the most recent batteries used. In most cases, the bq27510 can administrate information on two removable battery packs.

Activities Upon Pack Insertion

First Open-Circuit Impedance Measurement

Power-up the BAT_LOW/BAT_GD pin in active state. The system cannot obtain power from the battery (this depends on actual implementation). This state the battery put in an open-circuit condition. Next, the bq27510 measures its open-circuit voltage (OCV) via the BAT pin. From the OCV (SOC) table, SOG of the inserted battery is found. The BAT_LOW/BAT_GD pin is inactive, and the impedance of the inserted battery is calculated from the measured voltage and the current $Z(SOC) = OCV(SOC) / I(SOC)$. This impedance is compared with the impedance of the dynamic profiles, **Packn** and the default profiles, **Defn**, for the same SOC. The better depicts either a **0** or **1**.

Reading Application Status

The **ApplicationStatus** data location contains profile status information and can be read using the **ApplicationStatus** (Extended Command 0x6A). The bit configuration of this function/location is shown in [Table 2](#).

Table 2. ApplicationStatus_i Bit Definitions

bit1	bit2 Application Configuration	bit5	bit6	bit7						bit0
	Byte	-	-	-	-	-	-	LU_PROF		(1)

(1) LU_PROF: Last profile used by gauge. Cell0: Last used when cleared. Cell1: Last used when set Defaults.

APPLICATION-SPECIFIC FLOW AND CONTROL

The bq27510 supports only one type of battery profile. This profile is stored in both the **Def0** and **Def1** profiles. The **Defn** and **Packn** profiles are the same on the first gauge start-up. The impedance track™ algorithm begins gauging regularly updating **Packn** as the battery is used.

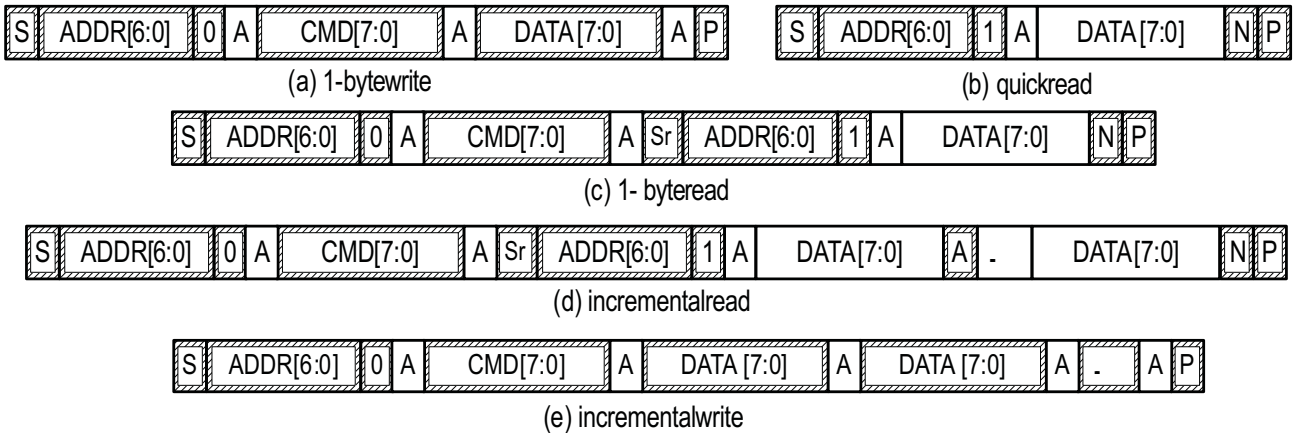
When existing packs are moved from the bq27510 and different (or same) packs inserted, cell impedance will be measured immediately after battery detection. The bq27510 chooses the profile which is closest to the measured impedance starting with the **Packn** profiles. That is, if the measured impedance matches **Pack0**, then the **Pack0** profile is used. If the measured impedance matches **Pack1**, then the **Pack1** profile is used. If the measured impedance does not match the impedance of either **Pack0** or **Pack1**, the battery packs **Def0/Def1** profile is copied into either the **Pack0** or **Pack1** profile, overwriting the oldest **Packn** profile used.

COMMUNICATIONS

I²C INTERFACE

The bq27510 supports the standard I²C read, incremental read, quick read, one-byte write, and incremental write functions. The 8-bit device address (ADDR) is the most significant bits of the address and is fixed as 1010101. The 8-bit device address will therefore be 0xA0 or 0xA5 for write or read, respectively.

Host generated bq27510 generated



(S = Start, Sr = Repeated Start, A = Acknowledge, N = No Acknowledge, and P = Stop).

Figure 4 Supported I²C Formats

The quick read returns data at the address indicated by the address pointer. The address pointer register internal to the I²C communication engine will increment whenever data is acknowledged by the bq27510 to the I²C master. Quick writes function in the same manner and are a convenient means of sending multiple bytes to consecutive command locations (such as two-byte commands that require two bytes of data).

The following command sequences are supported:

Attempt to write a read-only address (NACK after data sent by master):



Attempt to read an address above 0x6B (NACK command):



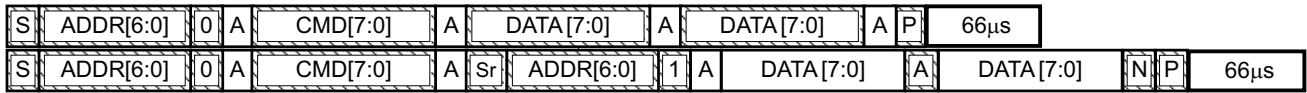
I²C TIMEOUT

The I²C engine will release both SDA and SCL if the I²C bus is held low for about 2 seconds. If the bq27510 was holding the lines, releasing them will free the master to drive the lines if external conditions holding either of the lines low. The I²C engine will enter the low power sleep mode.

I²C COMMAND WAITING TIME

To make sure the correct results of a command with a 400kHz I²C operation, proper waiting times should be added between issuing a command and reading its results. The following diagram shows the waiting times required between issuing the control command, the reading status, with the exception of checksum command. A 100ms waiting time is required between the checksum command and reading its result. For read-write standard commands, a minimum of 2 seconds is required before the result is updated. For read-only standard commands, there is no waiting time required, but the host should issue standard commands more than twice per second. Otherwise, the gauge could result in a false issue at the expiration of the watchdog timer.

COMMUNICATIONS(continued)



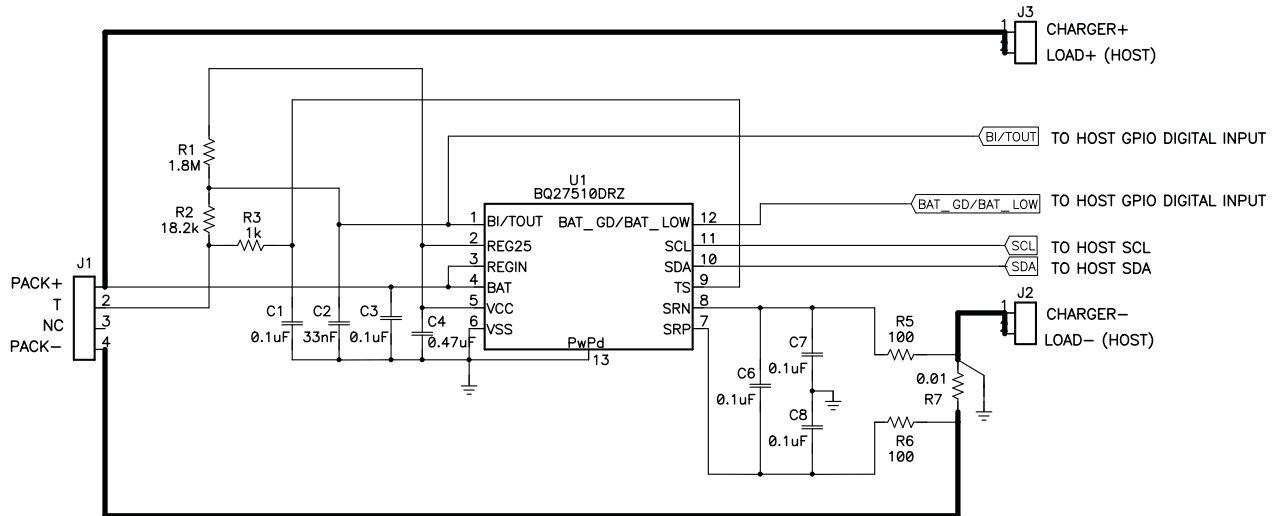
Waiting time between control subcommand and reading results



Waiting time between continuous reading results

The 2^{C} clock stretch could happen in a typical application. A maximum 80ms clock stretch could be observed during flash updates.

REFERENCE SCHEMATIC



PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/ Ball Finish	MSL Peak Temp ⁽³⁾	Samples (Requires Login)
BQ27510DRZR-G1	NRND	SON	DRZ	12	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
BQ27510DRZT-G1	NRND	SON	DRZ	12	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION



QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
BQ27510DRZR-G1	SON	DRZ	12	3000	330.0	12.4	2.8	4.3	1.2	4.0	12.0	Q2
BQ27510DRZT-G1	SON	DRZ	12	250	330.0	12.4	2.8	4.3	1.2	4.0	12.0	Q2

TAPE AND REEL BOX DIMENSIONS

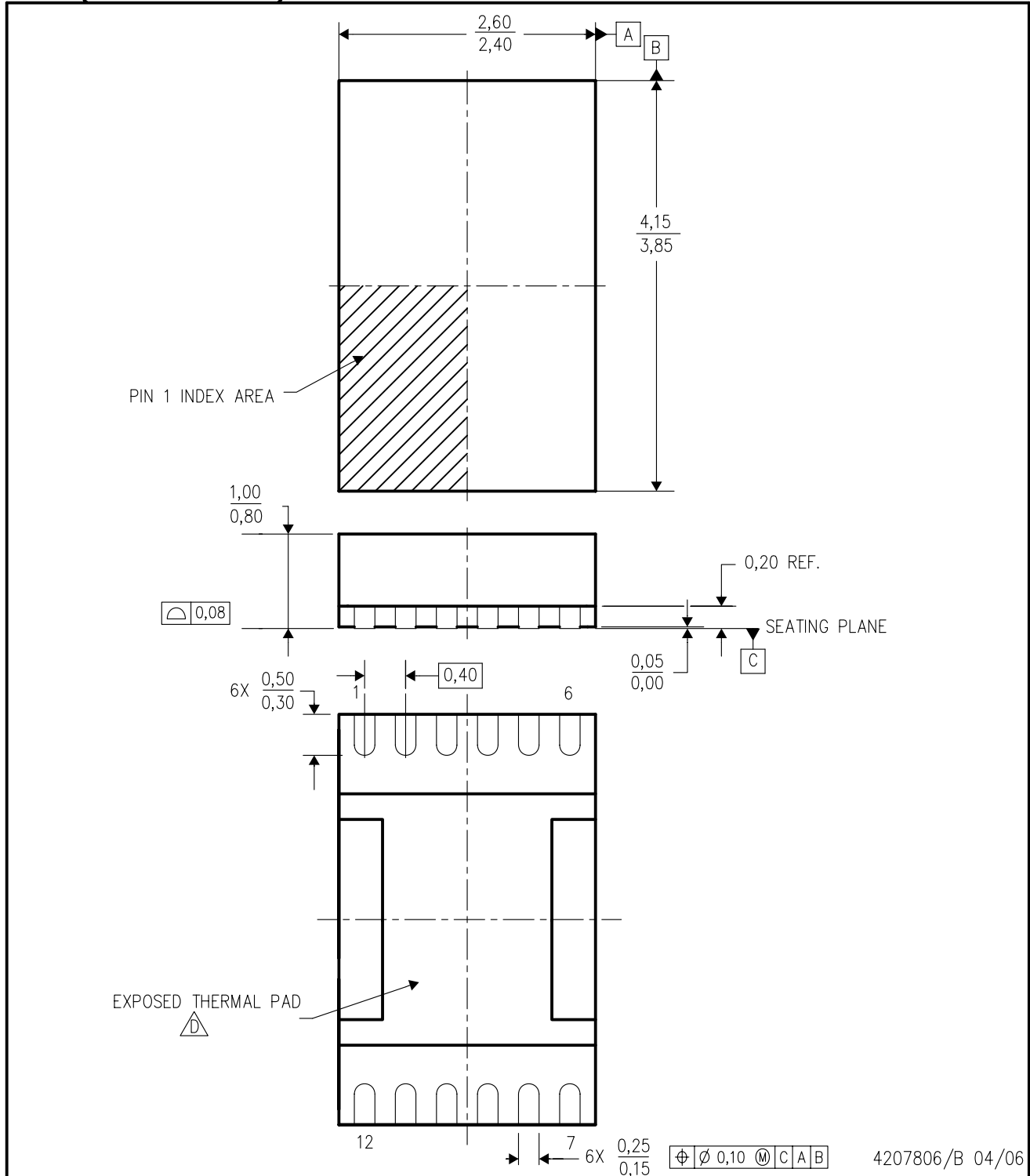


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
BQ27510DRZR-G1	SON	DRZ	12	3000	340.5	333.0	20.6
BQ27510DRZT-G1	SON	DRZ	12	250	340.5	333.0	20.6

DRZ (S-PDSO-N12)

PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 - B. This drawing is subject to change without notice.
 - C. Small Outline No-Lead (SON) package configuration.
 - Δ The package thermal pad must be soldered to the board for thermal and mechanical performance. See the Product Data Sheet for details regarding the exposed thermal pad dimensions.
 - E. This package is lead-free.

THERMAL PAD MECHANICAL DATA

DRZ (R-PDSO-N12)

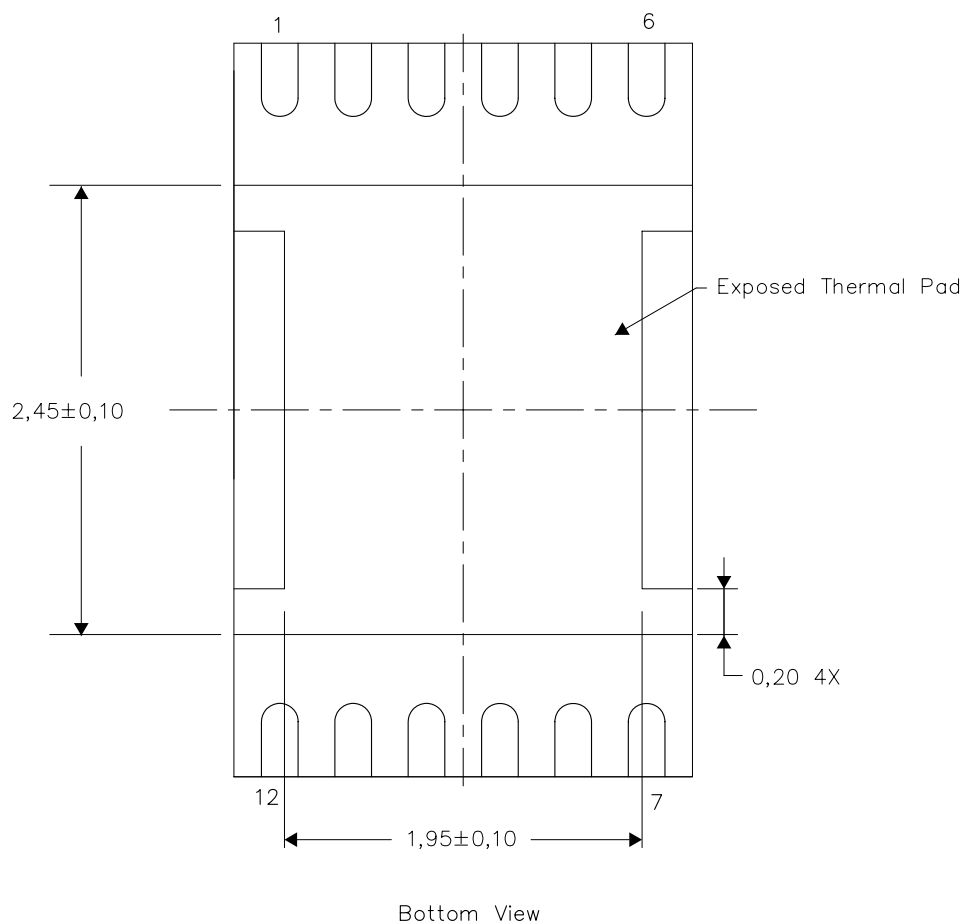
PLASTIC SMALL OUTLINE NO-LEAD

THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

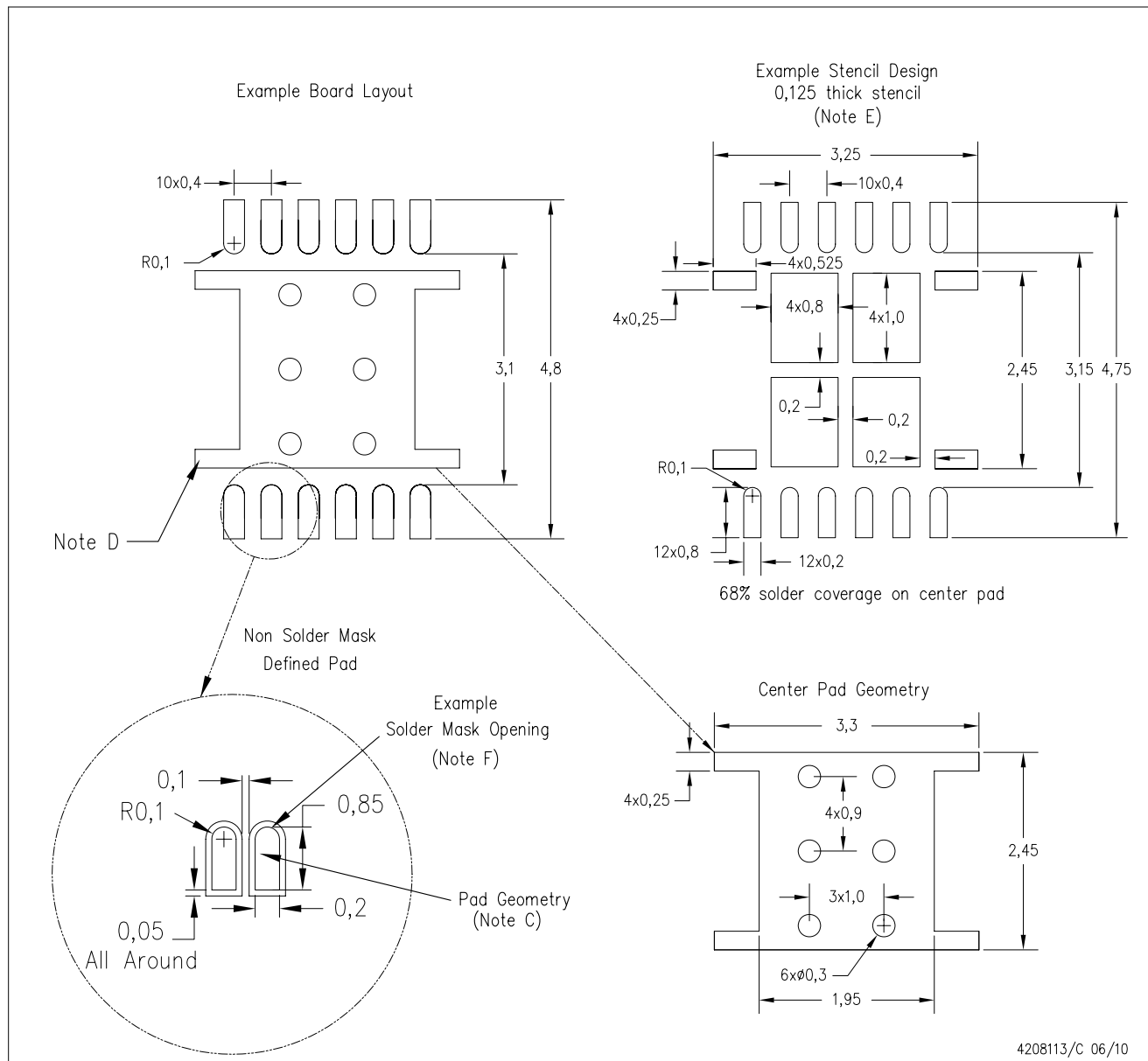
The exposed thermal pad dimensions for this package are shown in the following illustration.



NOTE: All linear dimensions are in millimeters

Exposed Thermal Pad Dimensions

4208114/E 06/10



- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Publication IPC-7351 is recommended for alternate designs.
 - D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat-Pack Packages, Texas Instruments Literature No. SCBA017, SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <<http://www.ti.com>>.
 - E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
 - F. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.

IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, modifications, enhancements, improvements, and other changes to its products and services at any time and to discontinue any product or service without notice. Customers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All products are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its hardware products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by government requirements, testing of all parameters of each product is not necessarily performed.

TI assumes no liability for applications assistance or customer product design. Customers are responsible for their products and applications using TI components. To minimize the risks associated with customer products and applications, customers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any TI patent right, copyright, mask work right, or other TI intellectual property right relating to any combination, machine, or process in which TI products or services are used. Information published by TI regarding third-party products or services does not constitute a license from TI to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. Reproduction of this information with alteration is an unfair and deceptive business practice. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI products or services with statements different from or beyond the parameters stated by TI for that product or service voids all express and any implied warranties for the associated TI product or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

TI products are not authorized for use in safety-critical applications (such as life support) where a failure of the TI product would reasonably be expected to cause severe personal injury or death, unless officers of the parties have executed an agreement specifically governing such use. Buyers represent that they have all necessary expertise in the safety and regulatory ramifications of their applications, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of TI products in such safety-critical applications, notwithstanding any applications-related information or support that may be provided by TI. Further, Buyers must fully indemnify TI and its representatives against any damages arising out of the use of TI products in such safety-critical applications.

TI products are neither designed nor intended for use in military/aerospace applications or environments unless the TI products are specifically designated by TI as military-grade or "enhanced plastic." Only products designated by TI as military-grade meet military specifications. Buyers acknowledge and agree that any such use of TI products which TI has not designated as military-grade is solely at the Buyer's risk, and that they are solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI products are neither designed nor intended for use in automotive applications or environments unless the specific TI products are designated by TI as compliant with ISO/TS 16949 requirements. Buyers acknowledge and agree that, if they use any non-designated products in automotive applications, TI will not be responsible for any failure to meet such requirements.

Following are URLs where you can obtain information on other Texas Instruments products and application solutions:

Products

Audio	www.ti.com/audio
Amplifiers	amplifier.ti.com
Data Converters	dataconverter.ti.com
DLP® Products	www.dlp.com
DSP	dsp.ti.com
Clocks and Timers	www.ti.com/clocks
Interface	interface.ti.com
Logic	logic.ti.com
Power Mgmt	power.ti.com
Microcontrollers	microcontroller.ti.com
RFID	www.ti-rfid.com
RF/IF and ZigBee® Solutions	www.ti.com/lprf

Applications

Communications and Telecom	www.ti.com/communications
Computers and Peripherals	www.ti.com/computers
Consumer Electronics	www.ti.com/consumer-apps
Energy and Lighting	www.ti.com/energy
Industrial	www.ti.com/industrial
Medical	www.ti.com/medical
Security	www.ti.com/security
Space, Avionics and Defense	www.ti.com/space-avionics-defense
Transportation and Automotive	www.ti.com/automotive
Video and Imaging	www.ti.com/video
Wireless	www.ti.com/wireless-apps

TI E2E Community Home Page

e2e.ti.com

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265
Copyright © 2011, Texas Instruments Incorporated